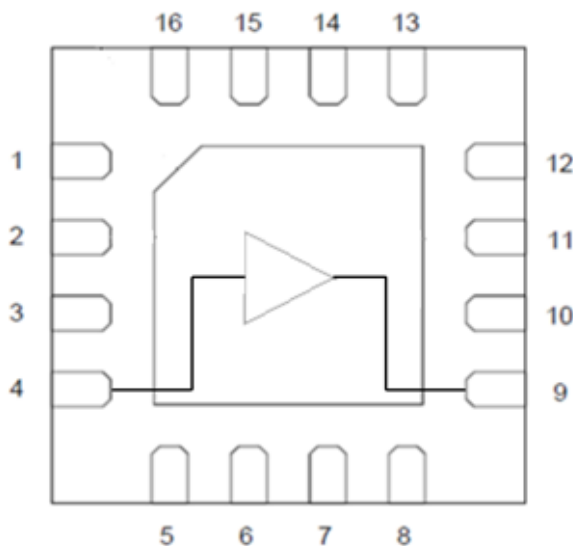


Product Overview

The QPL7425 is a GaAs pHEMT single ended RF amplifier IC featuring 25 dB of flat gain and low noise. This IC is designed for applications in the Upstream from 5MHz to 684MHz and in the Downstream from 47MHz to 1218MHz using a single 5V supply, and it can be used from 5V to 8V depending on linearity requirements. QPL7425 offers low noise and distortion plus high gain in a 3 x 3 QFN package for convenient layout and design in set top and infrastructure projects for 75 Ω CATV and satellite applications.

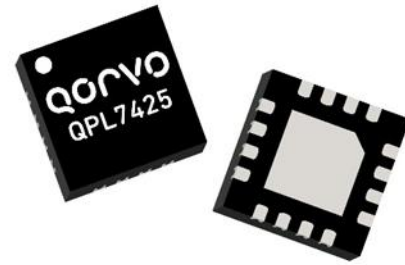
Functional Block Diagram



Top View

Ordering Information

| Part Number | Description |
|---------------|--------------------------------|
| QPL7425SB | Sample bag with 5 pieces |
| QPL7425SR | 7" Reel with 100 pieces |
| QPL7425TR7 | 7" Reel with 2500 pieces |
| QPL7425EVB-01 | 47 – 1218 MHz Evaluation Board |
| QPL7425EVB-02 | 5 – 684 MHz Evaluation Board |



3 x 3 QFN Package

Key Features

- 5 MHz to 1218 MHz Operation
- 5 V, and 8 V Operation
- Gain; 25 dB Typical
- Noise Figure; 1 dB Typical
- Adjustable Bias Using External Resistors
- Convenient QFN Package
- RoHS Compliant

Applications

- DOCSIS 3.1
- Upstream DOCSIS 3.1 and 4.0
- Downstream Applications, 47 to 1218 MHz
- Upstream Applications, 5 to 684 MHz
- Head End CMTS Equipment
- Optical Node and Amplifier
- FTTH GPON and GEON
- Satellite Low Noise Amplifier
- Cable Modem and Set Top Box
- Single Ended Gain Block

Absolute Maximum Ratings

| Parameter | Rating |
|--|----------------|
| Supply Voltage (V_{DD}) | +10 V |
| Supply Current (I_{DD}) | 140 mA |
| Maximum Input Level | 65 dBmV |
| Operating Temperature Range (Bottom of case) | -40 to +100 °C |
| Storage Temperature Range | -65 to +150 °C |
| Maximum Junction Temperature | +150 °C |

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Electrical Specifications, 47 – 1218 MHz (5 V)

| Parameter | Condition ⁽¹⁾ | Min | Typ | Max | Unit |
|-----------------------------|--------------------------------|-----|------|------|------|
| Supply Voltage (V_{DD}) | | | 5 | | V |
| Supply Current (I_{DD}) | | | 60 | | mA |
| Frequency Range | | 47 | | 1218 | MHz |
| Gain | | | 25 | | dB |
| Gain Slope | | | 0.9 | | dB |
| Reverse Isolation | | | -27 | | dB |
| Input Return Loss | | | 23 | | dB |
| Output Return Loss | | | 18 | | dB |
| Noise Figure | | | 1.0 | | dB |
| OIP2L | | | 44 | | dBm |
| OIP2H | | | 38 | | dBm |
| OIP3 | | | 35 | | dBm |
| OP1dB | | | 21 | | dBm |
| Thermal Resistance | Θ_{JC} (Bottom of Case) | | 28.8 | | °C/W |

Notes:

1. Typical performance at these conditions: Temp = +25 °C, V_{DD} = +5 V, 75 ohm system, Full band unless otherwise noted
2. OIP3; +9 dBm/ tone output, 6 MHz spacing
3. OIP2; +9 dBm/tone output, 30 MHz spacing

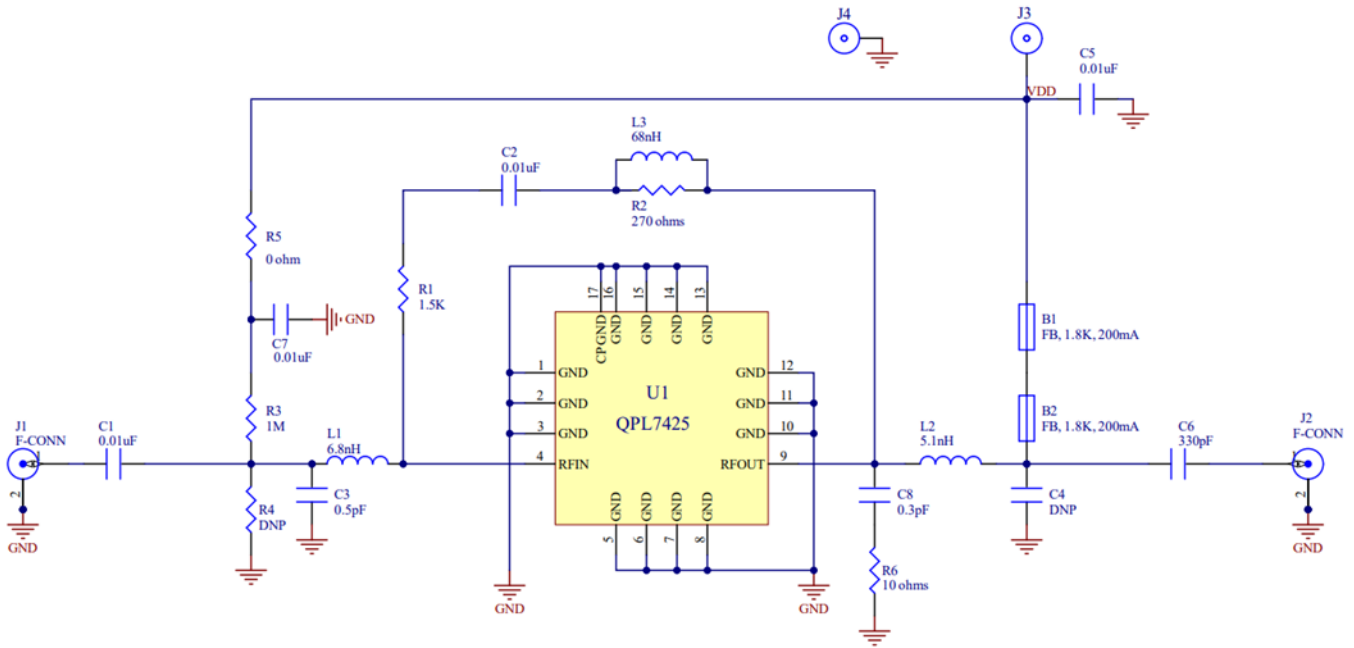
Electrical Specifications, 47 – 1218 MHz (8 V)

| Parameter | Condition ⁽¹⁾ | Min | Typ | Max | Unit |
|-----------------------------|--------------------------------|-----|------|------|-----------------------------|
| Supply Voltage (V_{DD}) | | | 8 | | V |
| Supply Current (I_{DD}) | | | 90 | | mA |
| Frequency Range | | 47 | | 1218 | MHz |
| Gain | | | 25 | | dB |
| Gain Slope | | | -1 | | dB |
| Reverse Isolation | | | -27 | | dB |
| Input Return Loss | | | 21 | | dB |
| Output Return Loss | | | -18 | | dB |
| Noise Figure | | | 1.0 | | dB |
| OIP2L | | | 51 | | dBm |
| OIP2H | | | 43 | | dBm |
| OIP3 | | | 40 | | dBm |
| OP1dB | | | 24 | | dBm |
| Thermal Resistance | Θ_{JC} (Bottom of Case) | | 28.8 | | $^{\circ}\text{C}/\text{W}$ |

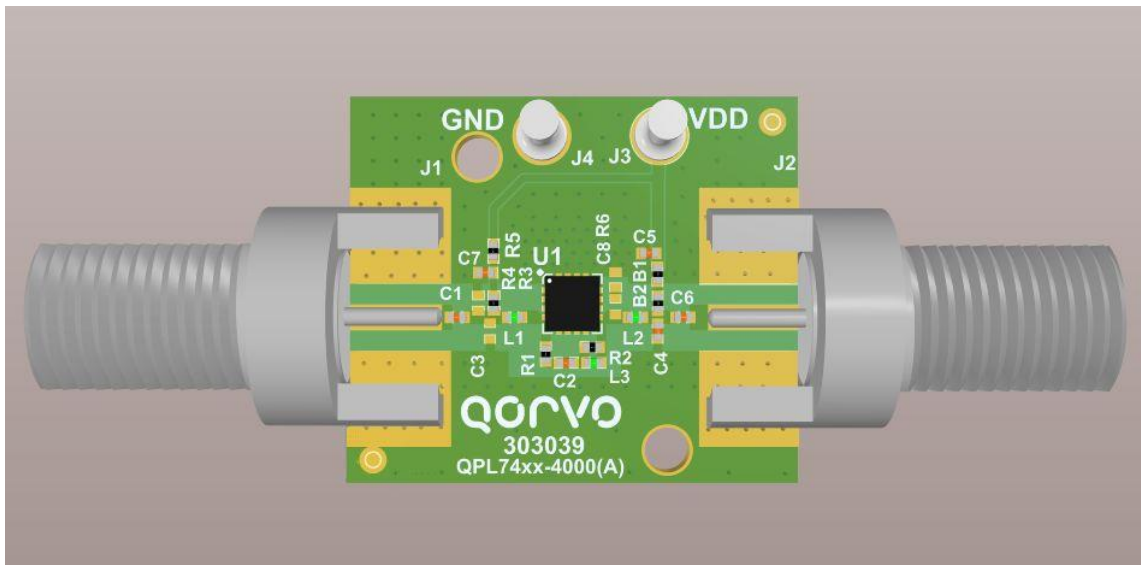
Notes:

1. Typical performance at these conditions: Temp = +25 $^{\circ}\text{C}$, V_{DD} = +8 V, 75 ohm system, Full band unless otherwise noted
2. OIP3; +9 dBm/ tone output, 6 MHz spacing
3. OIP2; +9 dBm/tone output, 30 MHz spacing

Evaluation Board Schematic, 47 – 1218 MHz



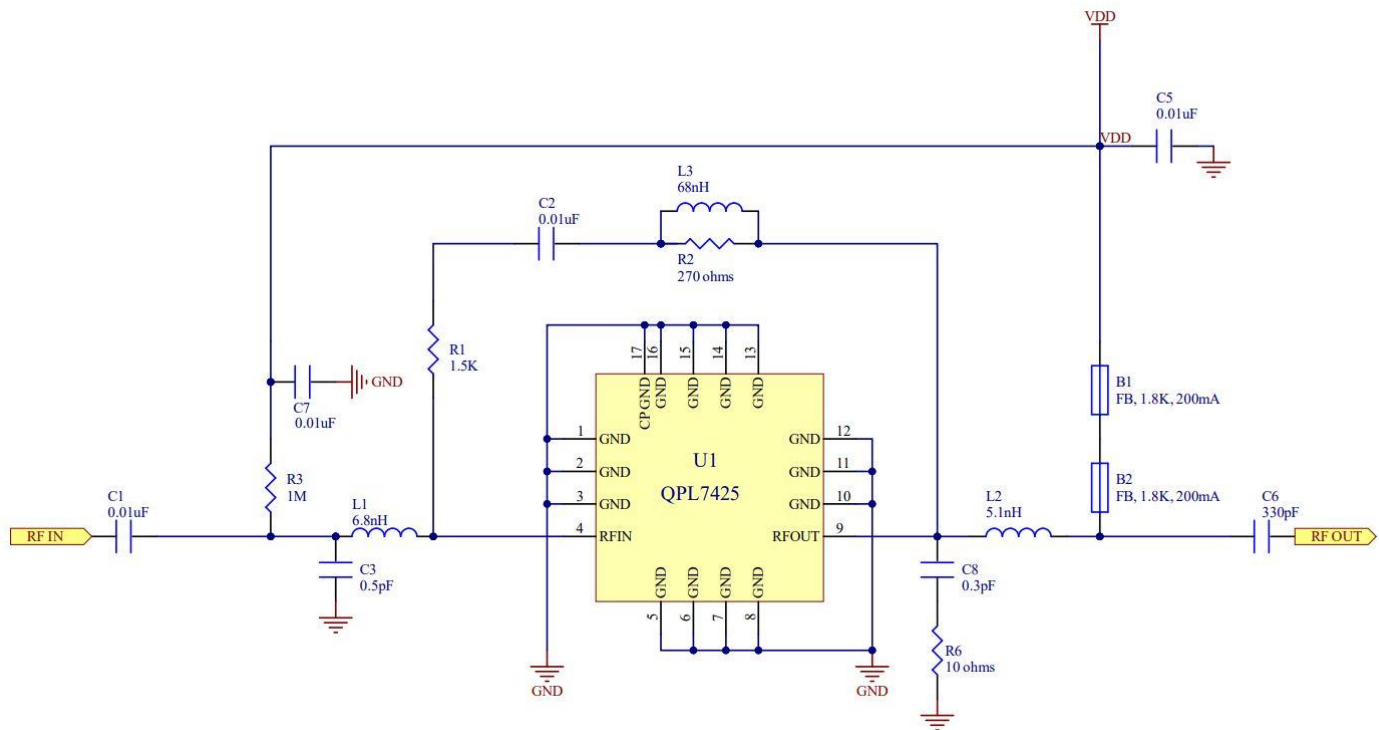
Evaluation Board Assembly Drawing, 47 – 1218 MHz



Evaluation Board Bill of Materials, 47 – 1218MHz

| Designator | Description | Manufacturer | Part Number |
|----------------|---|------------------------------|-------------------------|
| PCB | QPL74xx-4000 | TTM | QPL74xx-4000(A) |
| U1 | 25dB FTTH Amplifier | Qorvo | QPL7425 |
| B1, B2 | FER, BEAD, 1.8K, 200mA, 0402 | TDK | MMZ1005A182ET000 |
| C1, C2, C5, C7 | CAP, 0.01uF, 10%, 50V, X7R, 0402 | Murata Electronics | GCM155R71H103KA55D |
| C3 | CAP, 0.5pF, +/-0.1pF, 50V, HI-Q, 0402 | Murata Electronics | GJM1555C1HR50BB01D |
| C6 | CAP, 330pF, 10%, 50V, X8L, 0402 | Murata Electronics | GCM155L81H331KA37D |
| C8 | CAP, 0.3pF, +/-0.05pF, 50V, HI-Q, 0402 | Murata Electronics | GJM1555C1HR30WB01D |
| J1, J2 | CONN, F FEM EDGE MOUNT, 75 OHMS, 0.068" | Millimeter Wave Technologies | MW-846-C-DD-75 |
| J3, J4 | TERM. SOLDER TURRET, 0.062 PCB | Mill-Max Manufacturing | 2533-0-00-44-00-00-07-0 |
| L1 | IND, 6.8nH, 5%, M/L, 0402 | Murata Electronics | LQG15HN6N8J02D |
| L2 | IND, 5.1nH, +/- 0.3nH, 300mA, M/L, 0402 | Murata Electronics | LQG15HS5N1S02D |
| L3 | IND, 68nH, 2%, 250mA, M/L, 0402 | Murata Electronics | LQG15HS68NG02D |
| R1 | RES, 1.5K, 5%, 1/16W, 0402 | Kamaya, Inc | RMC1/16S-152JTH |
| R2 | RES, 270 OHM, 5%, 1/16W, 0402 | Kamaya, Inc | RMC1/16S-271JTH |
| R3 | RES, 1M, 5%, 1/16W, 0402 | Kamaya, Inc | RMC1/16S-105JTH |
| R5 | RES, 0 OHM, 5%, 1/10W, 0402 | Kamaya, Inc | RMC1/16SJPTH |
| R6 | RES, 10 OHM, 5%, 1/16W, 0402 | Kamaya, Inc | RMC1/16S-100JTH |
| C4, R4 | Not Populated | | |

Typical Application Schematic, 47 – 1218 MHz



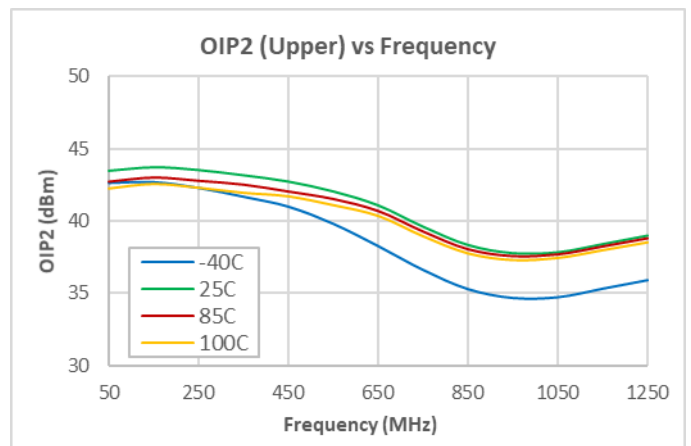
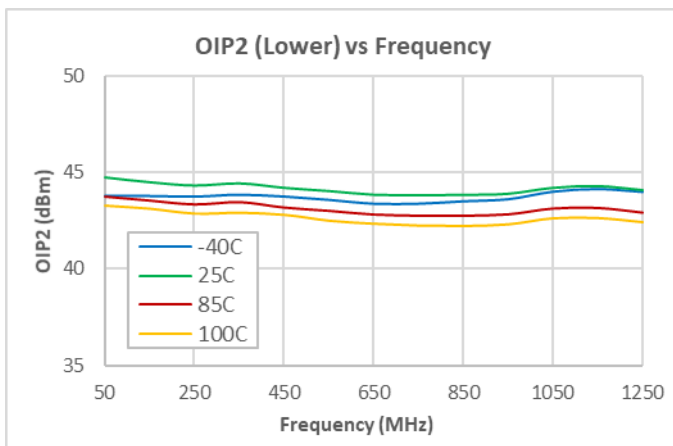
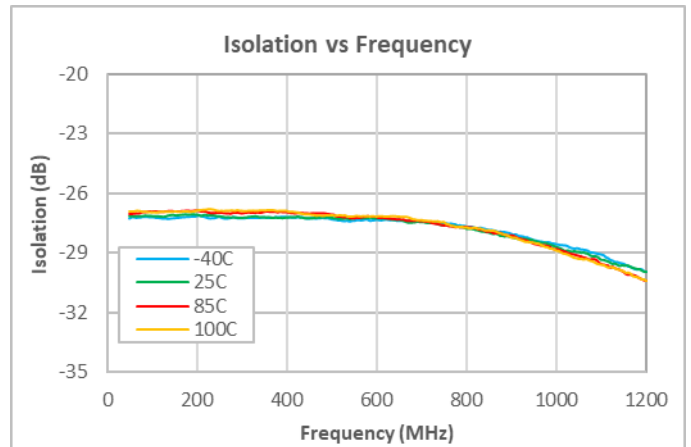
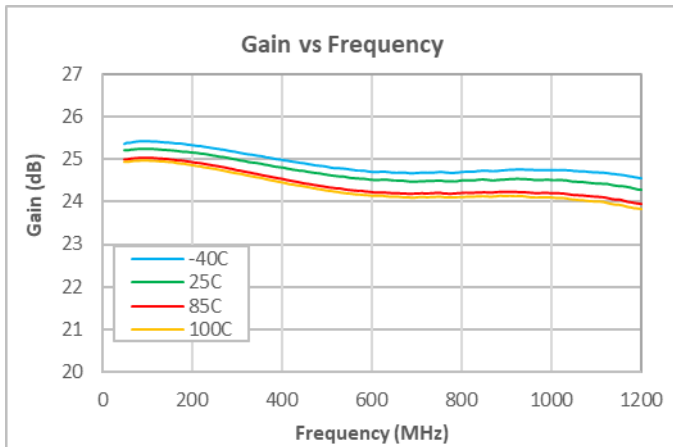
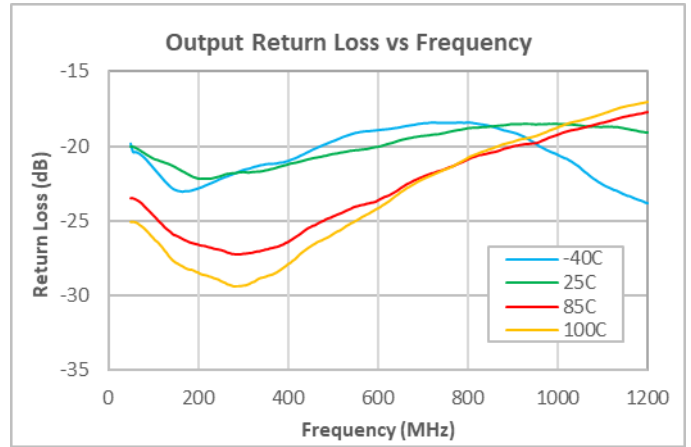
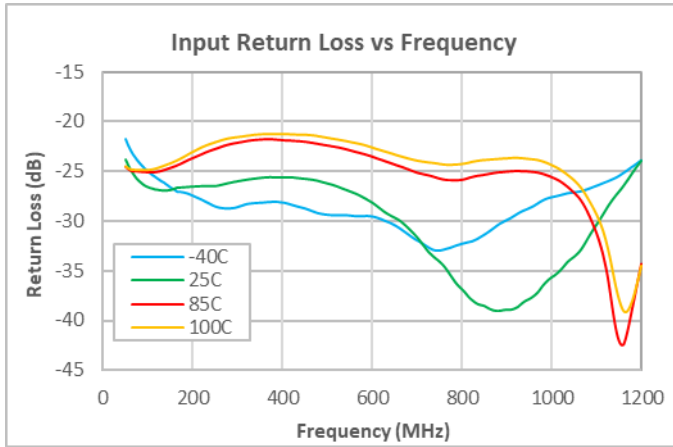
Notes:

1. C3/L1 tunes input return loss.
2. L2/C8 tunes output return loss with some contribution from C6.
3. The feedback network is composed of R1 and R2, with C2 being a DC block and L3 providing high end peaking. The ratio of R1 to R2 controls flatness and tilt while the total feedback resistance affects device gain.
4. B1, B2 provides the bias path with RF isolation from the RF output path.
5. R3 is adjusted to increase linearity or shed power.

Table 1, Pullup Resistor Options

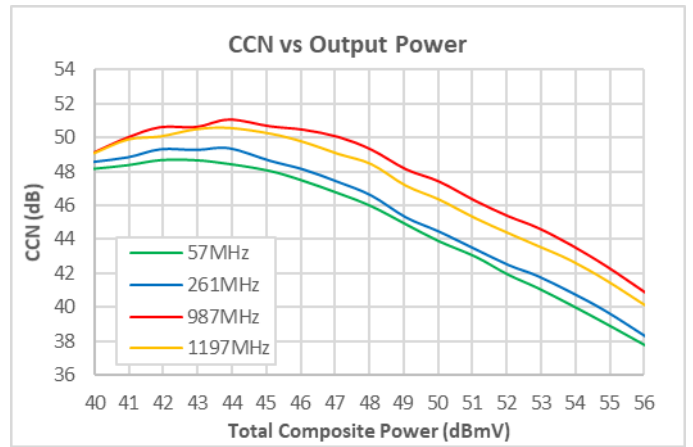
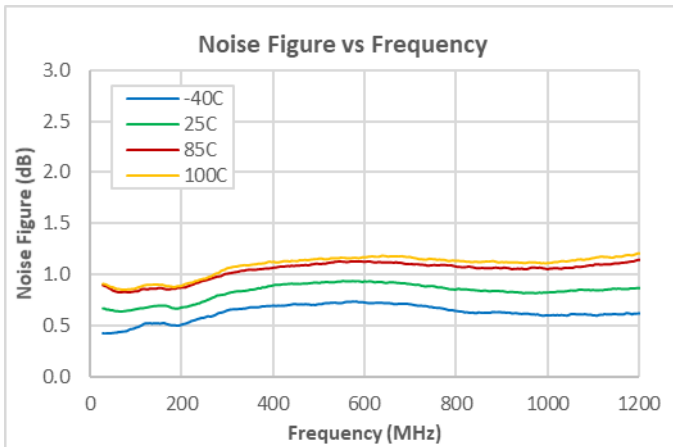
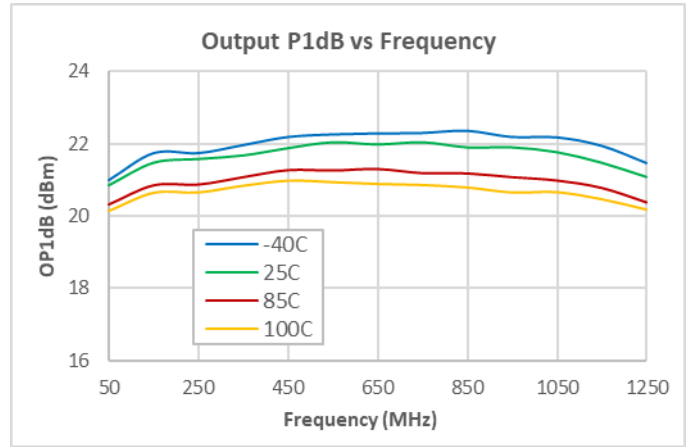
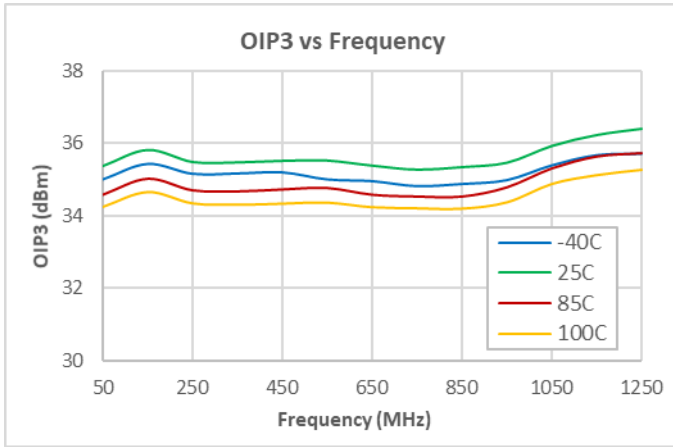
| Bias Current vs R3/R4 | | | |
|-----------------------|-----------------------|------------|-------------|
| R3 Pullup (ohms) | R4 Pulldown (ohms) | VDD (V) | IDD (mA) |
| DNP | DNP | 8 | 80 |
| 1M | DNP | 8 | 90 |
| 680K | DNP | 8 | 100 |
| 360K | DNP | 8 | 120 |
| DNP | DNP | 5 | 50 |
| 1M | DNP | 5 | 60 |
| 300K | DNP | 5 | 80 |
| 120K | DNP | 5 | 120 |

Performance Data, 47 – 1200 MHz (5 V)



- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) OIP2: 9 dBm/tone output, 50 MHz spacing.

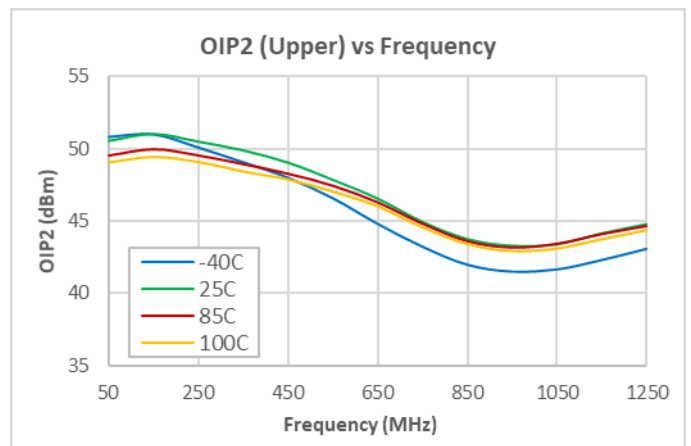
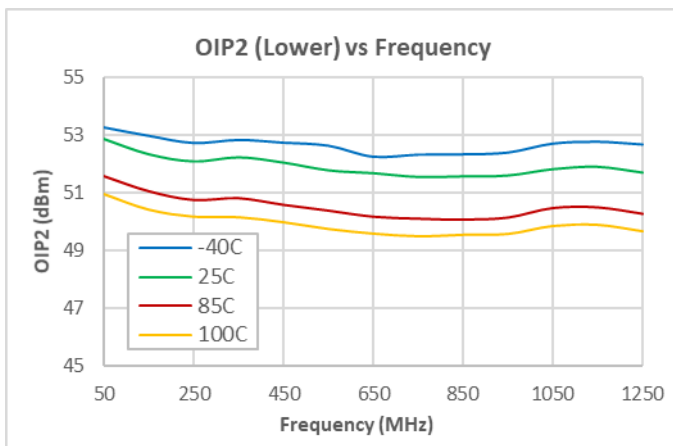
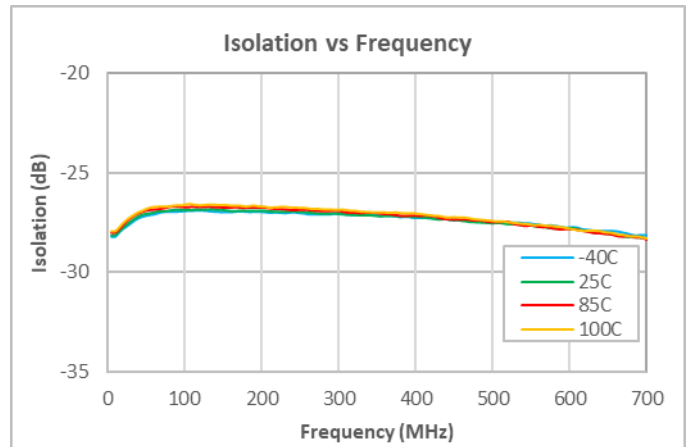
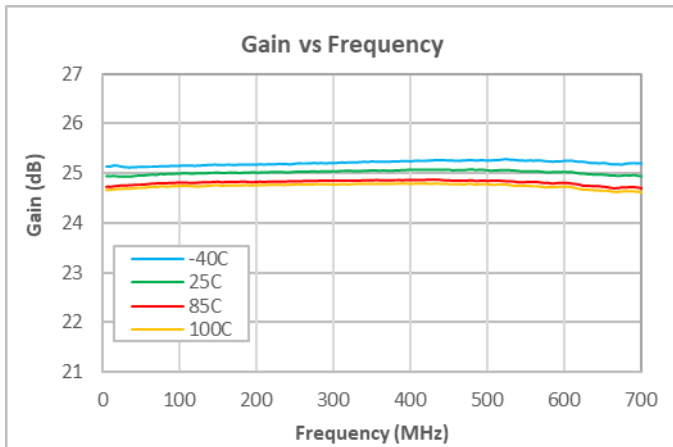
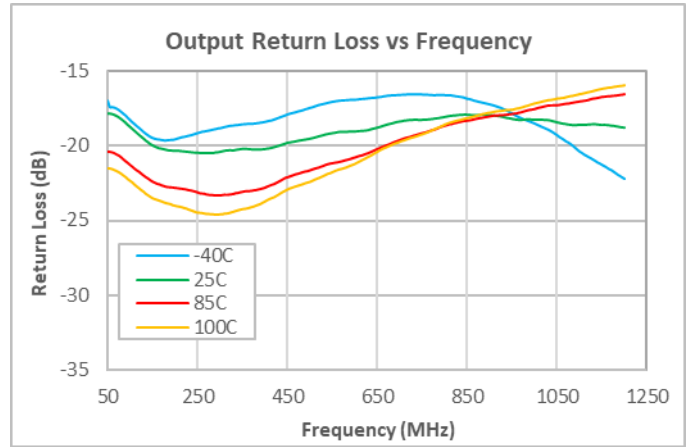
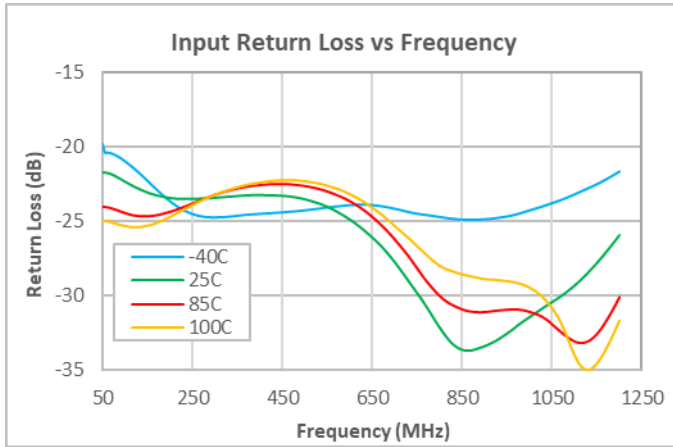
Performance Data, 47 – 1200 MHz (5 V)



Notes:

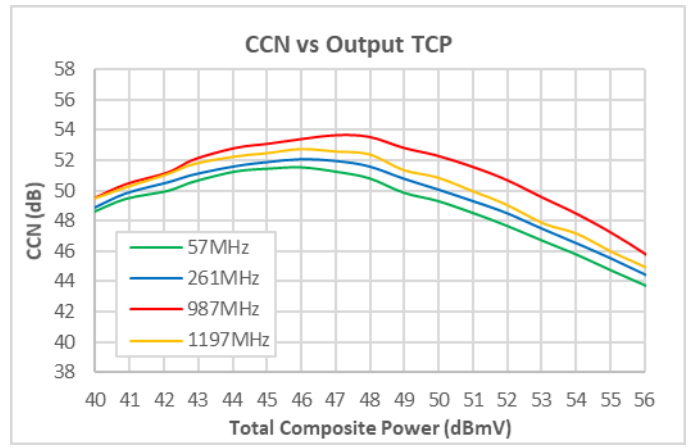
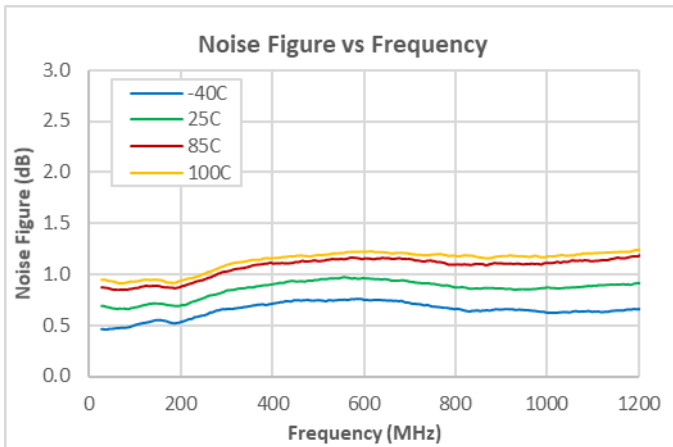
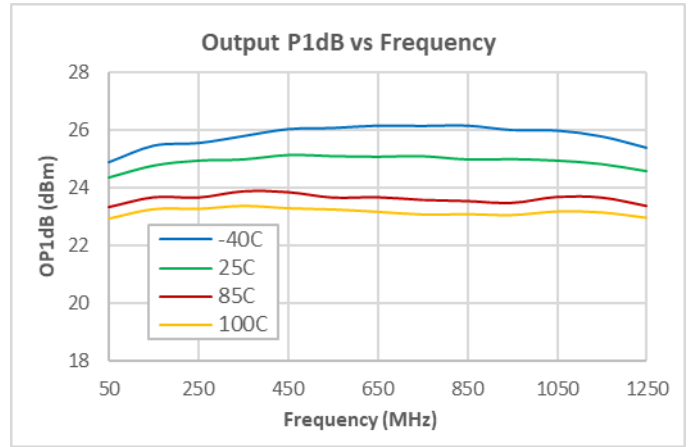
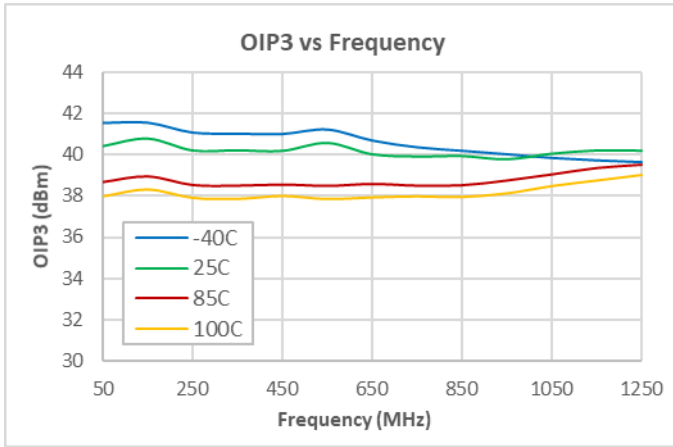
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP3: 9 dBm / tone output, 6 MHz spacing.
- (3) CCN: 57 – 1215 MHz SC QAM, 0 dB Tilt.

Performance Data, 47 – 1200 MHz (8 V)



- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) OIP2: 9 dBm/tone output, 30 MHz spacing.

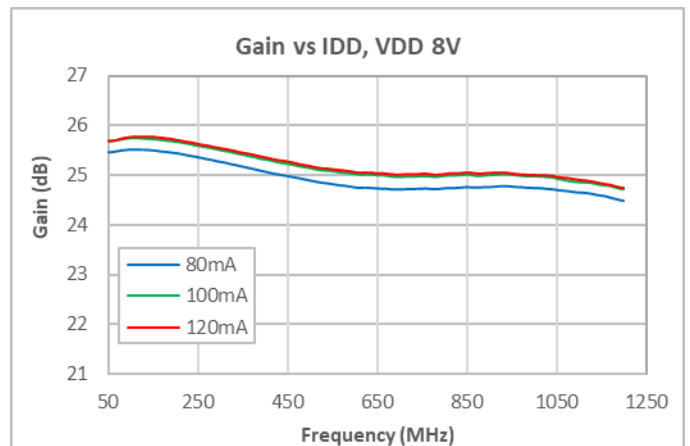
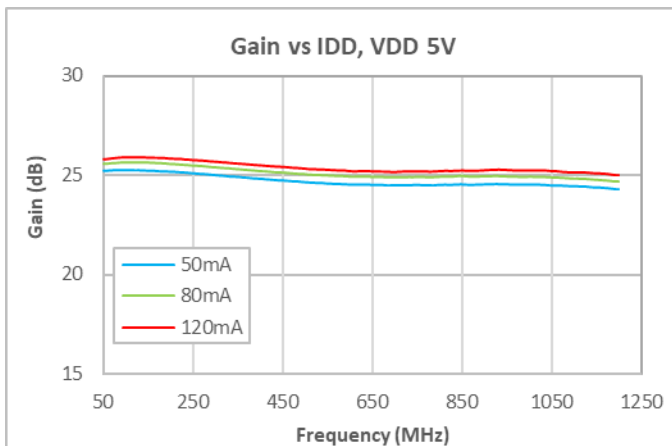
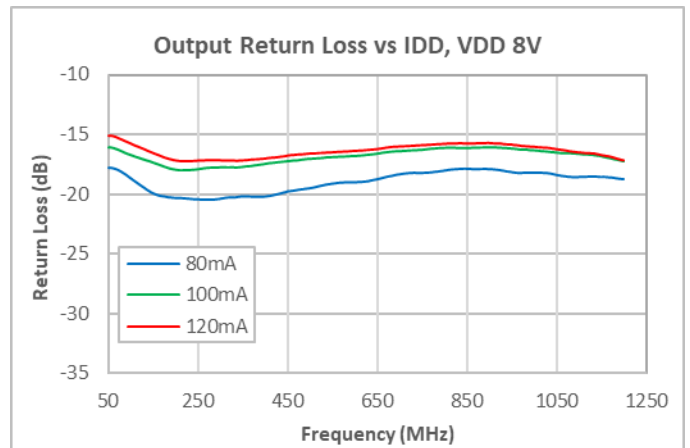
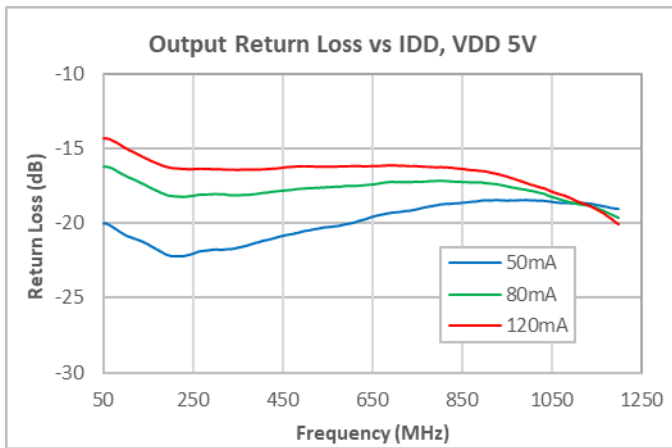
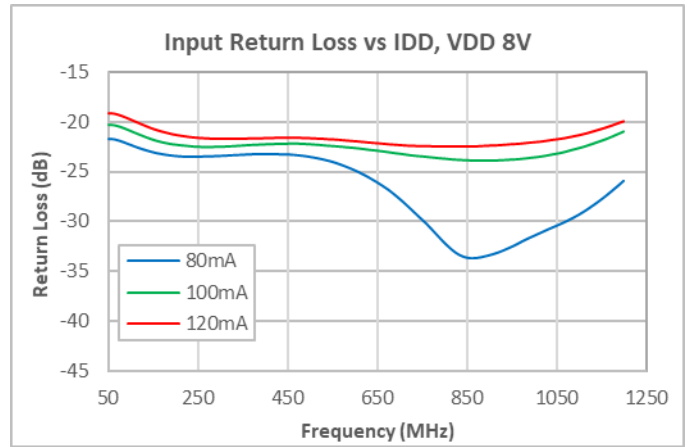
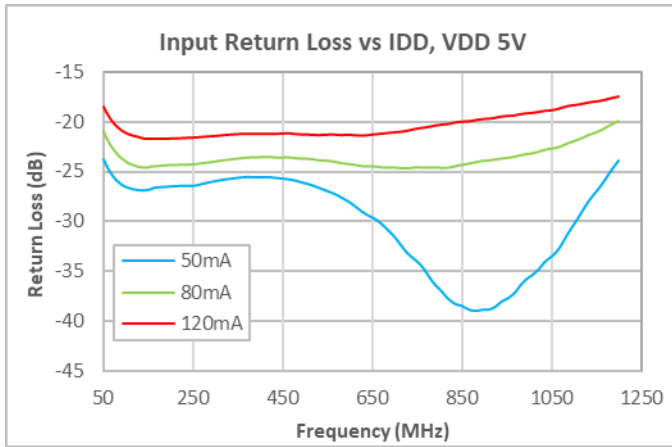
Performance Data, 47 – 1200 MHz (8 V)



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP3: 9 dBm / tone output, 6 MHz spacing.
- (3) CCN: 57 – 1215 MHz SC QAM, 0 dB Tilt.

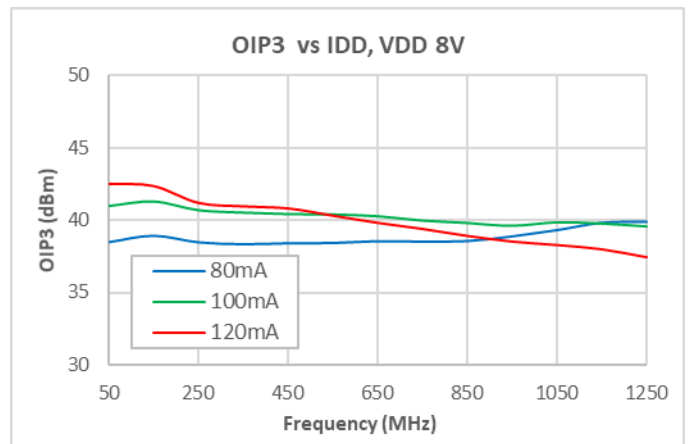
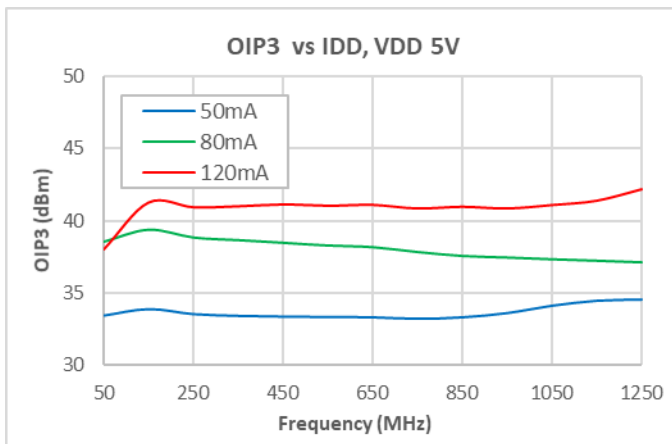
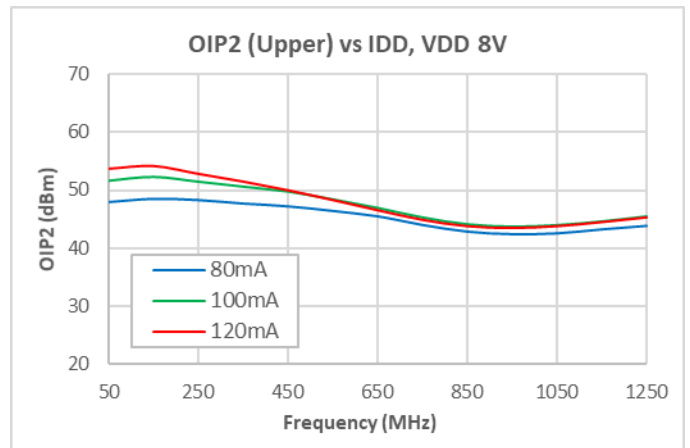
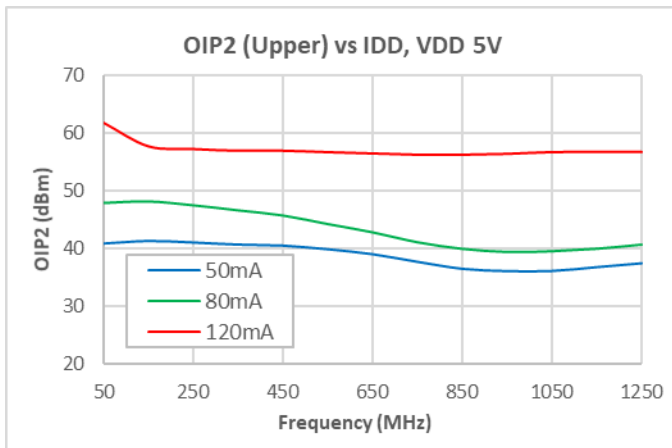
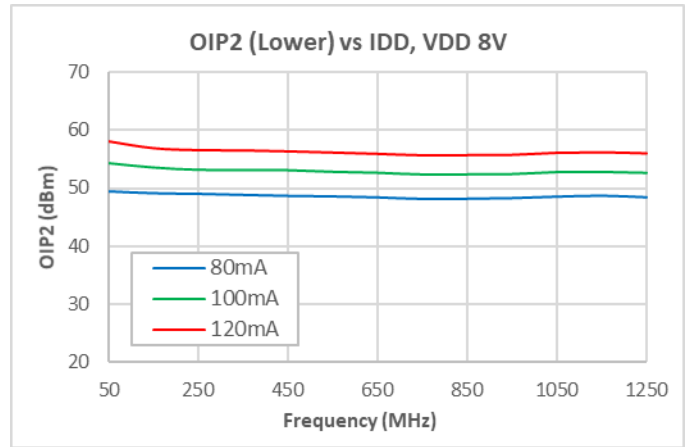
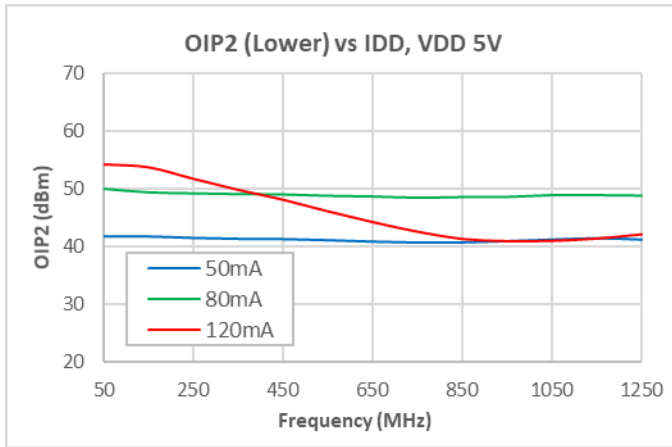
Performance Data vs Supply Voltage, 47 – 1200 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).

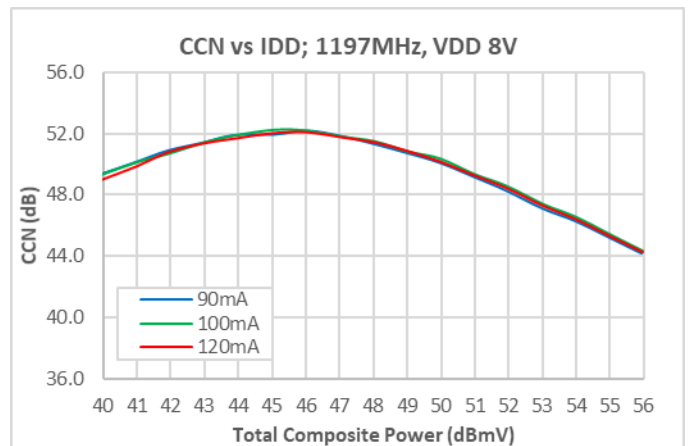
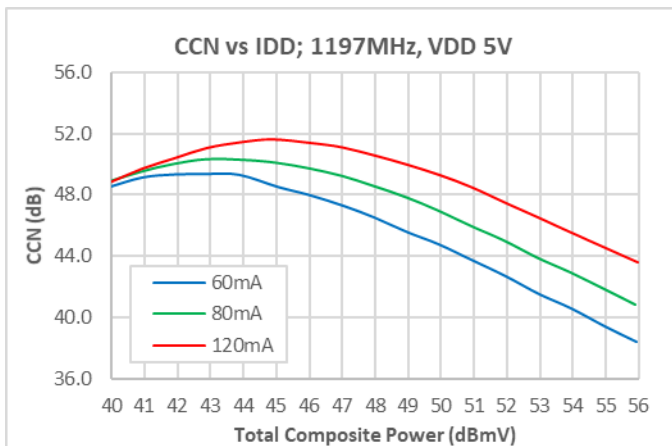
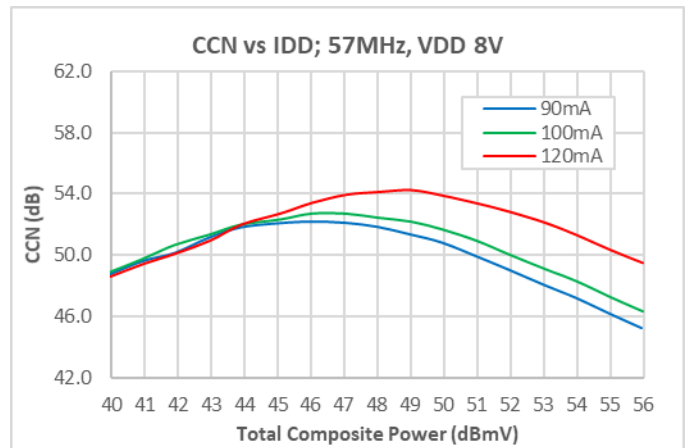
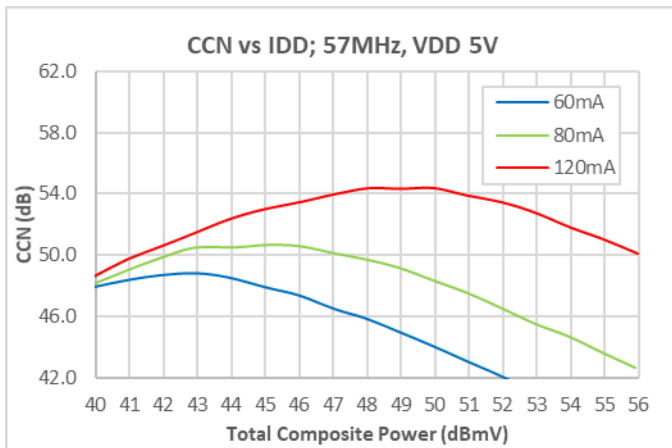
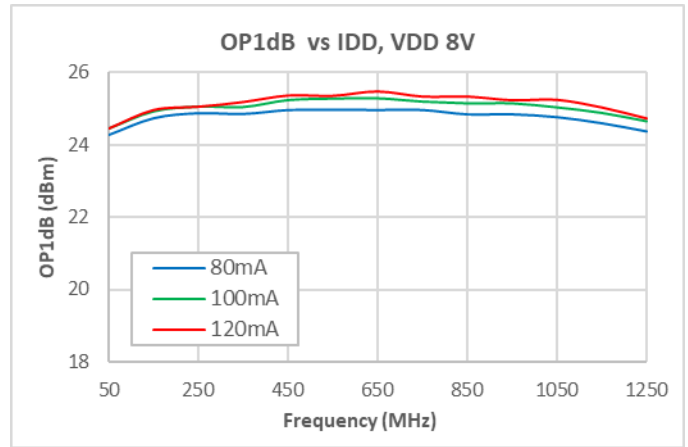
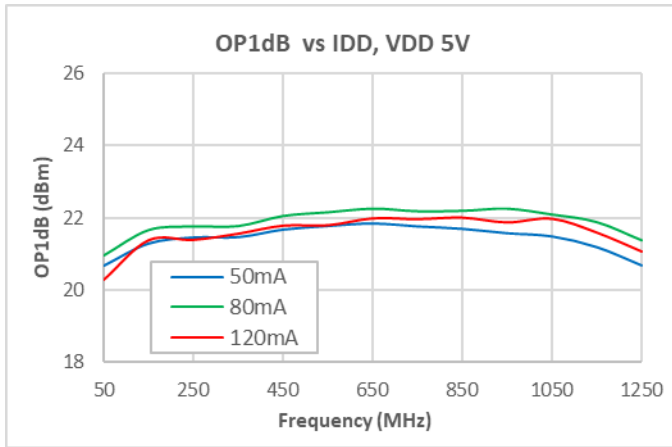
Performance Data vs Supply Voltage, 47 – 1200 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP2; 9 dBm/tone, 30 MHz spacing.
- (3) OIP3; 9 dBm/tone, 6 MHz spacing.

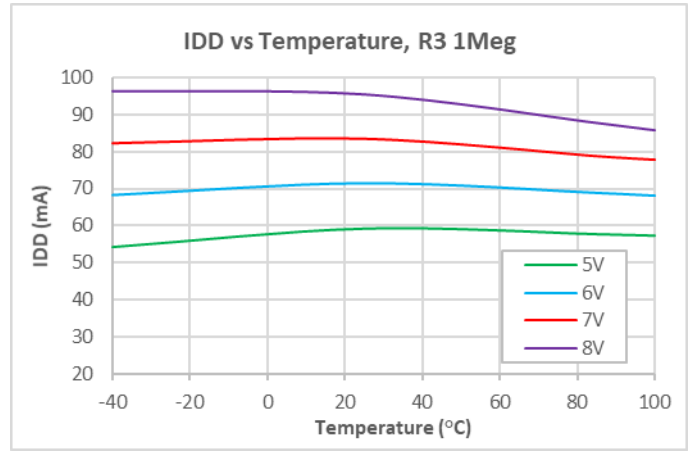
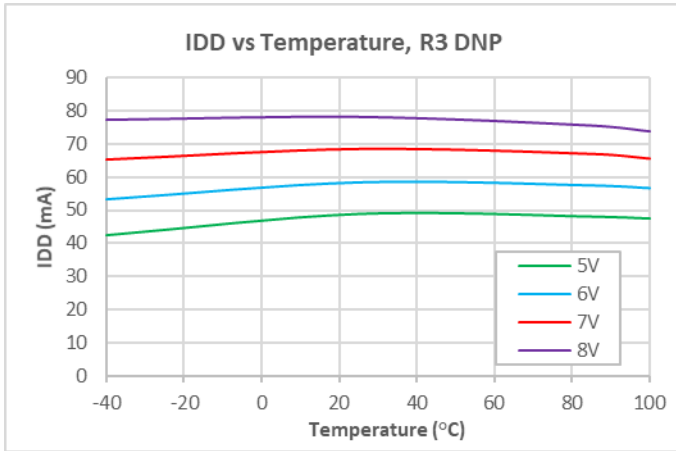
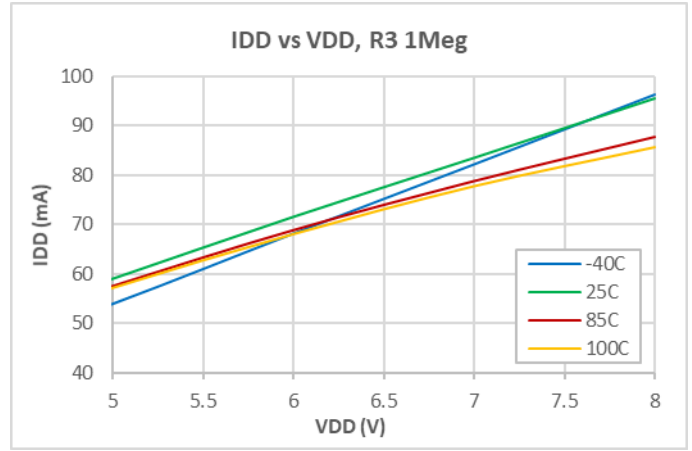
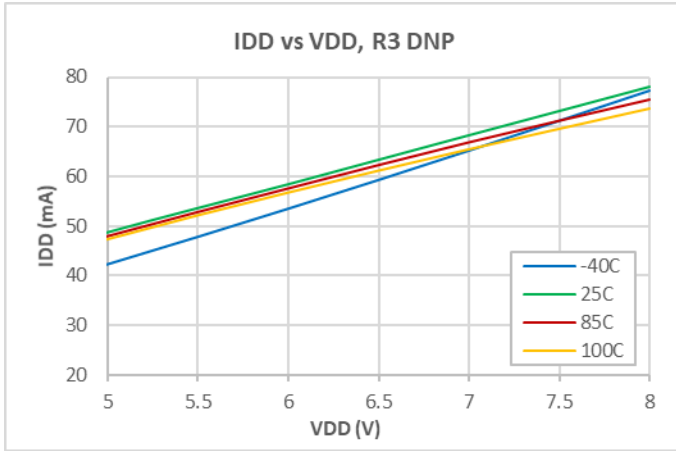
Performance Data vs Supply Voltage, 47 – 1200 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) CCN: 57 – 1215 MHz SC QAM.

Performance Data vs Supply Voltage, 47 – 1200 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).

Electrical Specifications, 5 – 700 MHz (5 V)

| Parameter | Condition ⁽¹⁾ | Min | Typ | Max | Unit |
|-----------------------------|---|-----|------|-----|-----------------------------|
| Supply Voltage (V_{DD}) | | | 5 | | V |
| Supply Current (I_{DD}) | | | 50 | | mA |
| Frequency Range | | 5 | | 700 | MHz |
| Gain | | | 25 | | dB |
| Gain Slope | | | 0.0 | | dB |
| Reverse Isolation | | | -27 | | dB |
| Input Return Loss | | | 18 | | dB |
| Output Return Loss | | | 19 | | dB |
| Noise Figure | | | 1.0 | | dB |
| MER | At 48.1 dBmV TCP, 5 - 204 MHz, 0dB tilt, 33ch 256QAM ITU-T J.83, Annex B | | 45 | | dB |
| OIP2L | | | 40 | | dBm |
| OIP2H | | | 37 | | dBm |
| OIP3 | | | 33 | | dBm |
| OP1dB | 204 MHz | | 22 | | dBm |
| Thermal Resistance | Θ_{JC} , Bottom of Case | | 28.8 | | $^{\circ}\text{C}/\text{W}$ |

Notes:

1. Typical performance at these conditions: Temp = +25 $^{\circ}\text{C}$, V_{DD} = +5V, 75 ohm system, Full band unless otherwise noted
2. OIP3; +9 dBm/ tone output, 6 MHz spacing
3. OIP2; +9 dBm/tone output, 30 MHz spacing

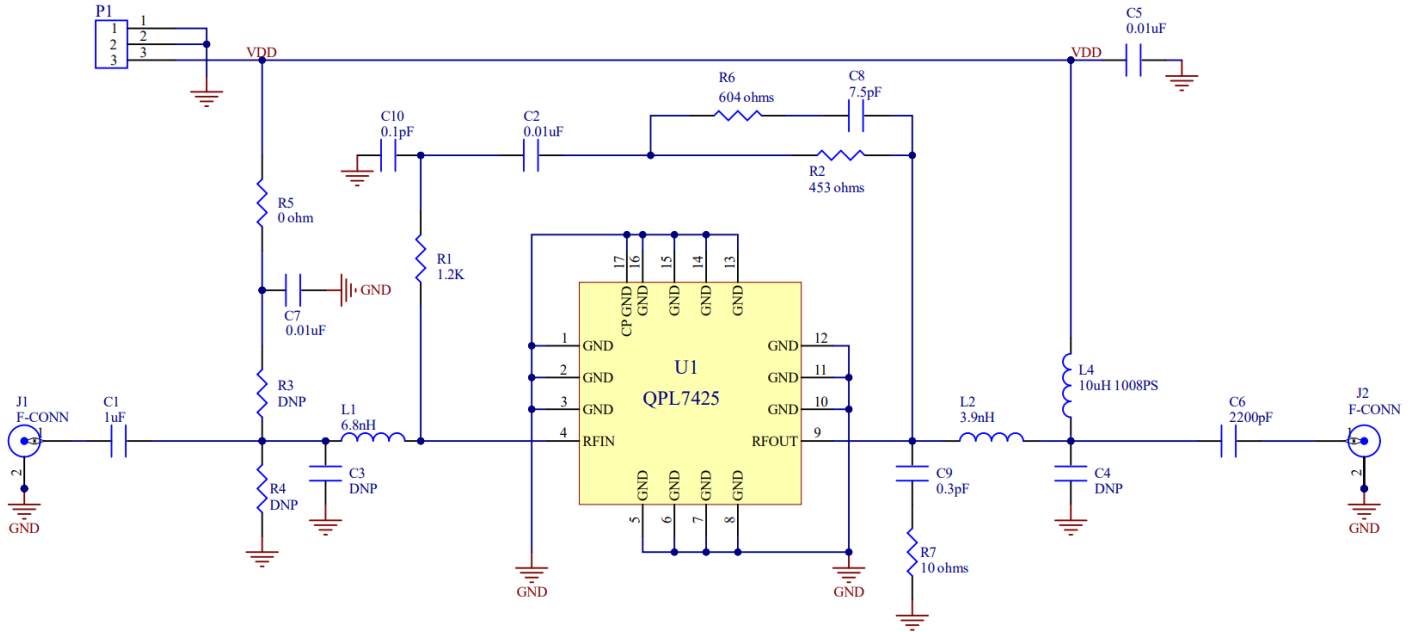
Electrical Specifications, 5 – 700 MHz (8 V)

| Parameter | Condition ⁽¹⁾ | Min | Typ | Max | Unit |
|-----------------------------------|--|-----|------|-----|------|
| Supply Voltage (V _{DD}) | | | 8 | | V |
| Supply Current (I _{DD}) | | | 80 | | mA |
| Frequency Range | | 5 | | 700 | MHz |
| Gain | | | 25.4 | | dB |
| Gain Slope | | | 0.0 | | dB |
| Reverse Isolation | | | -27 | | dB |
| Input Return Loss | | | 19 | | dB |
| Output Return Loss | | | 18 | | dB |
| Noise Figure | | | 1.0 | | dB |
| MER | At 55.2 dBmV TCP, 5 - 204 MHz, 0 dB tilt, 33 ch 256 QAM ITU-T J.83, Annex B | | 45 | | dB |
| OIP2L | | | 47 | | dBm |
| OIP2H | | | 43 | | dBm |
| OIP3 | | | 38 | | dBm |
| OP1dB | 204 MHz | | 25 | | dBm |
| Thermal Resistance | Θ _{JC} , Bottom of Case | | 28.8 | | °C/W |

Notes:

1. Typical performance at these conditions: Temp = +25 °C, V_{DD} = +5 V, 75 ohm system, Full band unless otherwise noted
2. OIP3; +9 dBm/ tone output, 6 MHz spacing
3. OIP2; +9 dBm/tone output, 30 MHz spacing

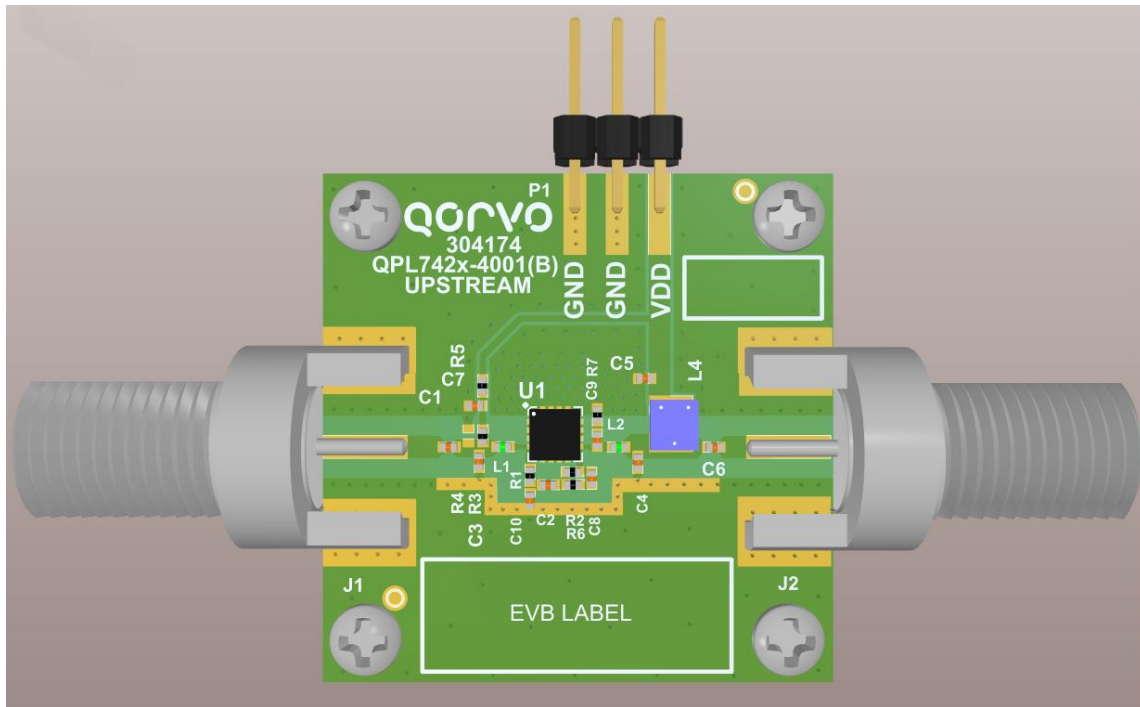
Evaluation Board Schematic, 5 – 700 MHz



Notes:

1. C3/L1 tunes input return loss.
2. L2/C4 tunes output return loss with some contribution from C6.
3. C9/R7 can also be used for output return loss tuning if needed for bandwidth limiting and stability enhancement.
4. R1, R2, and the blocking cap, C2 are the basic feedback loop for setting gain.
5. C8 and R6 in parallel with R2 help improve gain flatness at low frequency.
6. C10 improves gain slope when C8 and R6 are present.
7. L4 provides the bias path with RF isolation from the RF output path. A variety of RF chokes may be used as long as sufficient inductance is provided to ensure good performance at 5MHz with bias without causing unwanted behavior out of band.
8. R3 and R4 are used to change the bias current bias current for desired linearity and NPR dynamic range (Refer to Table 1).

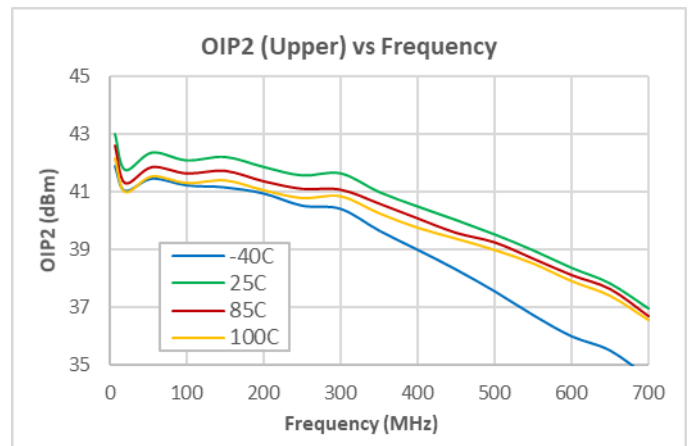
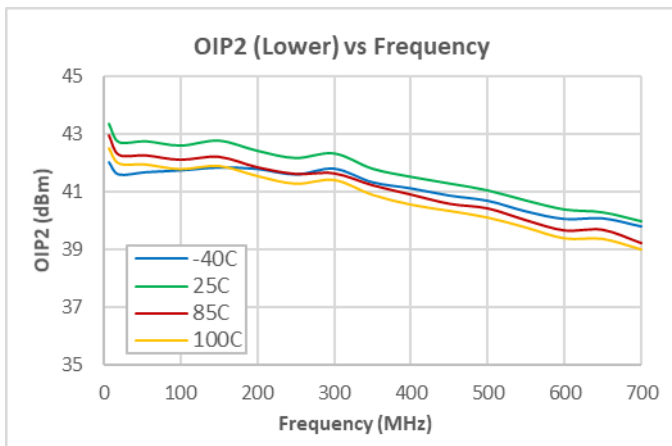
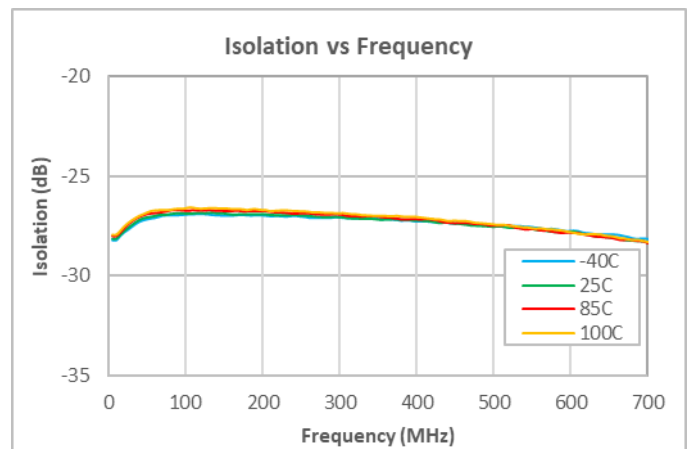
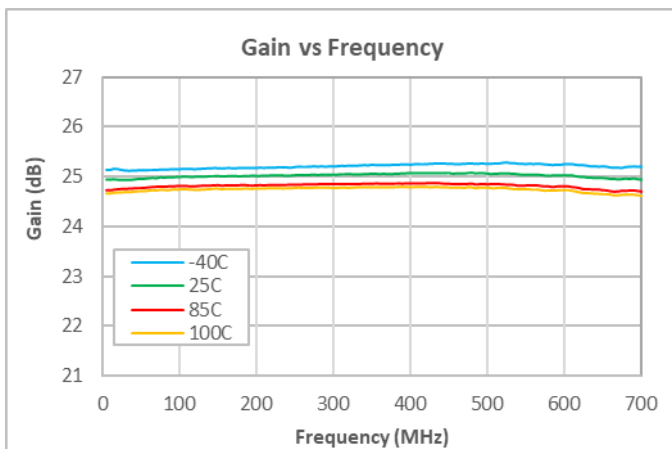
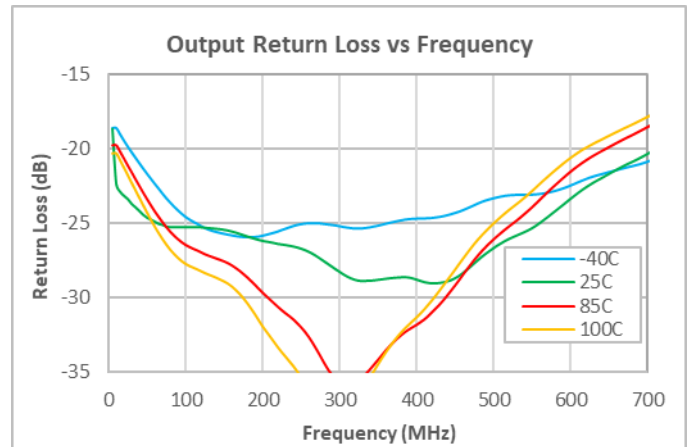
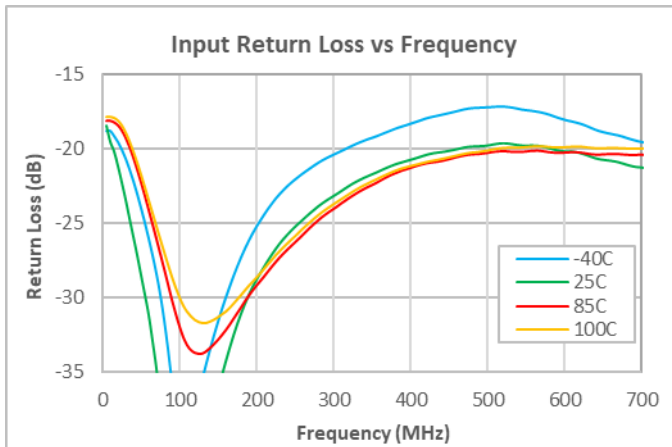
Evaluation Board Assembly Drawing, 5 – 700 MHz



Evaluation Board Bill of Materials, 5 – 700 MHz

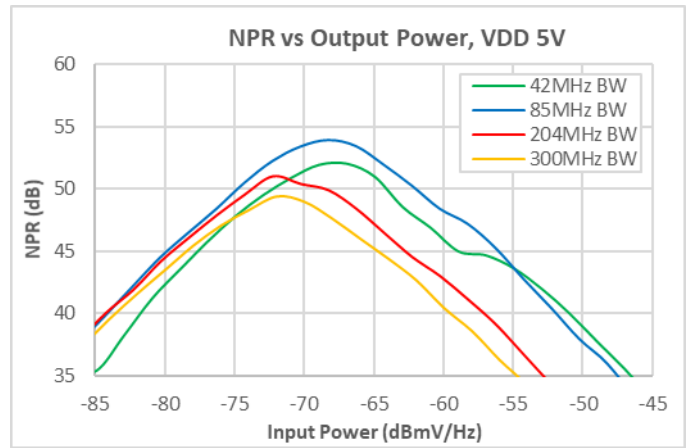
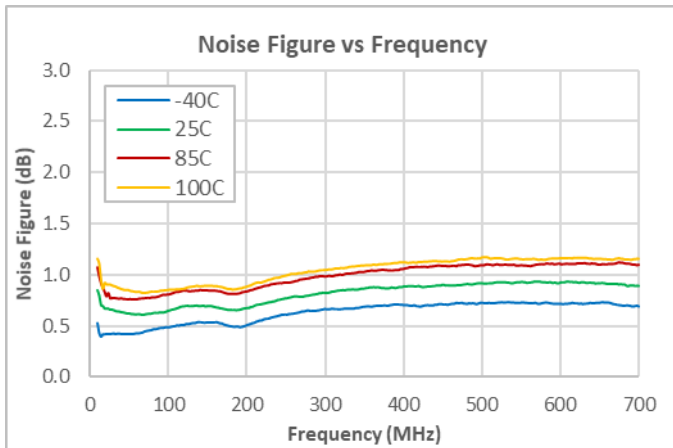
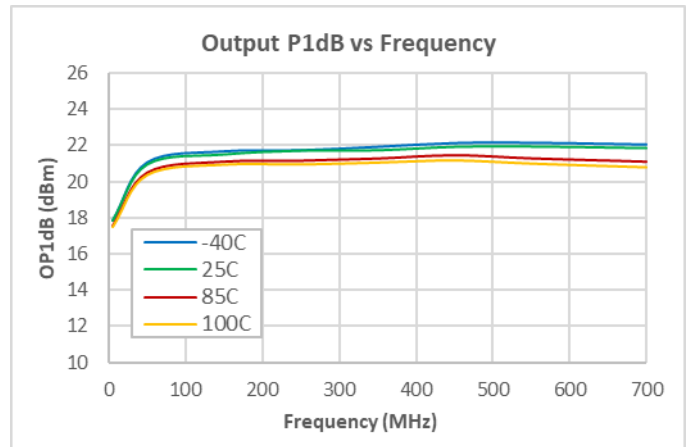
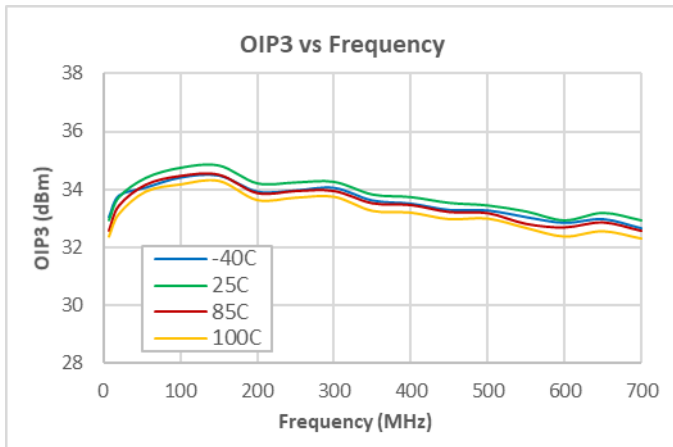
| Designator | Description | Manufacturer | Part Number |
|----------------|--|------------------------------|--------------------|
| PCB | QPL7425-4001 | TTM | QPL7425-4001(B) |
| U1 | 20dB FTTH Amplifier | Qorvo | QPL7425 |
| C1 | CAP, 1uF, 20%, 16V, X5R, 0402 | Murata | GRM155R61C105MA12D |
| C2, C5, C7 | CAP, 0.01uF, 10%, 50V, X7R, 0402 | Murata | GCM155R71H103KA55D |
| C9 | CAP, 0.3pF, +/-0.05pF, 50V, HI-Q, 0402 | Murata | GJM1555C1HR30WB01D |
| C10 | CAP, 0.1pF, +/-0.05pF, 50V, HI-Q, 0402 | Murata | GJM1555C1HR10WB01D |
| C6 | CAP, 2200pF, 5%, 50V, X7R, 0402 | Murata | GRM155R71H222JA01D |
| C8 | CAP, 7.5pF, +/-0.1pF, 50V, HI-Q, 0402 | Murata | GJM1555C1H7R5BB01D |
| L1 | IND, 6.8nH, 2%, 600mA, M/L, 0402 | Murata | LQG15HS6N8G02D |
| L2 | IND, 3.9nH, +/-0.3nH, M/L, 0402 | Murata | LQG15HN3N9S02D |
| L4 | IND, 10uH, 10%, 1A, W/W, 1008 | Coilcraft | 1008PS-103KRC |
| R1 | RES, 1.2K, 5%, 1/16W, 0402 | Kamaya | RMC1/16S-122JTH |
| R2 | RES, 453 OHM, 1%, 1/16W, 0402 | Yageo | RC0402FR-07453RL |
| R5 | RES, 0 OHM, 5%, 1/10W, 0402 | Kamaya | RMC1/16SJPTH |
| R6 | RES, 604 OHM, 1%, 1/10W, 0402 | Kamaya | RMC1/16SK6040FTH |
| R7 | RES, 10 OHM, 5%, 1/16W, 0402 | Kamaya | RMC1/16S-100JTH |
| J1, J2 | CONN, F FEM EDGE MOUNT, 75 OHMS, 0.068" | Millimeter Wave Technologies | MW-846-C-DD-75 |
| P1 | CONN, HDR, ST, 1x3, 0.100", HI-TEMP, T/H | Samtec Inc. | HTSW-103-07-G-S |
| Heat Sink | HEATSINK BLOCK, 1.16 SQ I | Robert S. Wells | EEF-102059 |
| Screws | SCREW, 2-56X3/16", SOCKET HD | McMaster-Carr Supply Co. | 92196A076 |
| C3, C4, R3, R4 | Not Populated Item | | |

Performance Data, 5 – 700 MHz (5 V)



- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) OIP2; +9 dBm/tone output, 30 MHz spacing

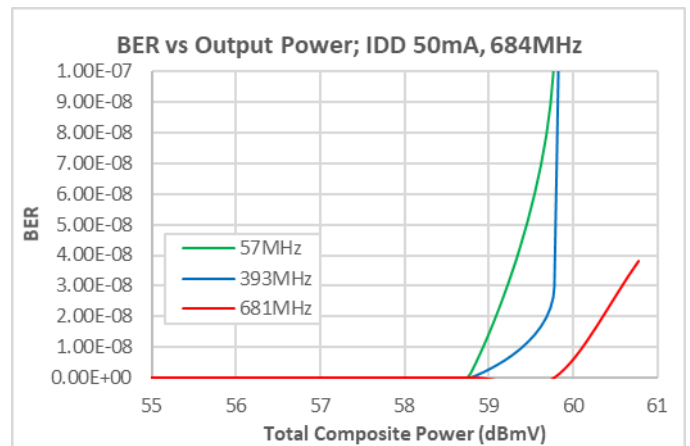
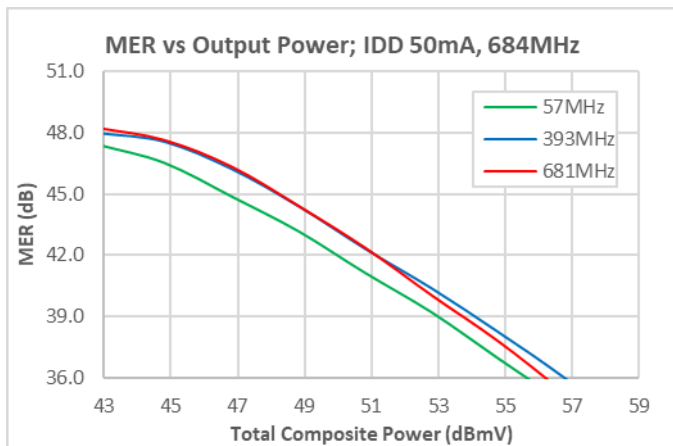
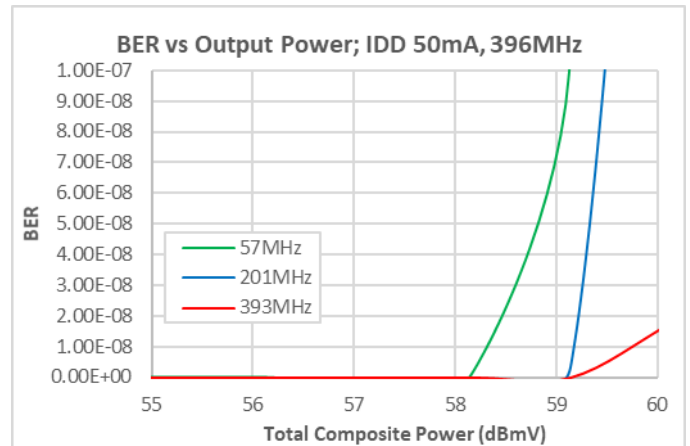
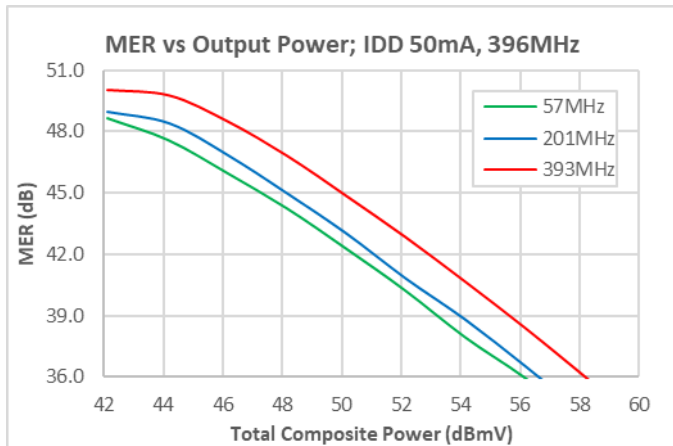
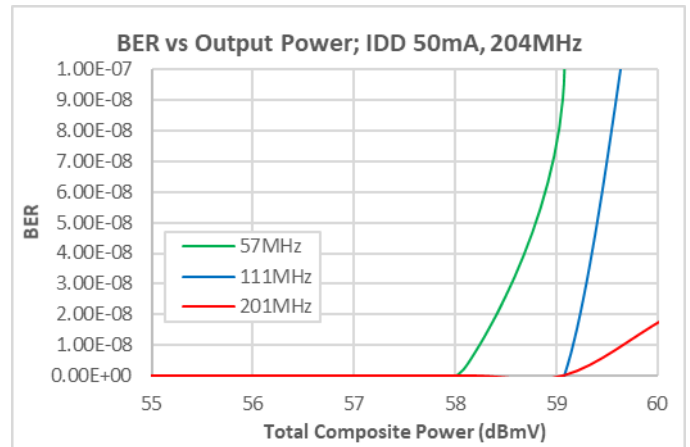
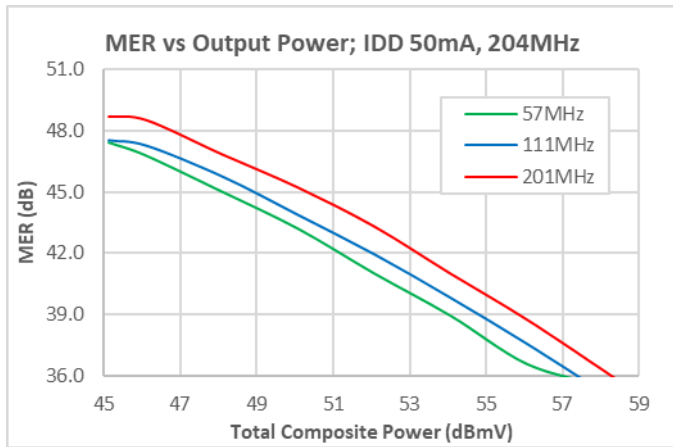
Performance Data, 5 – 700 MHz (5 V)



Notes:

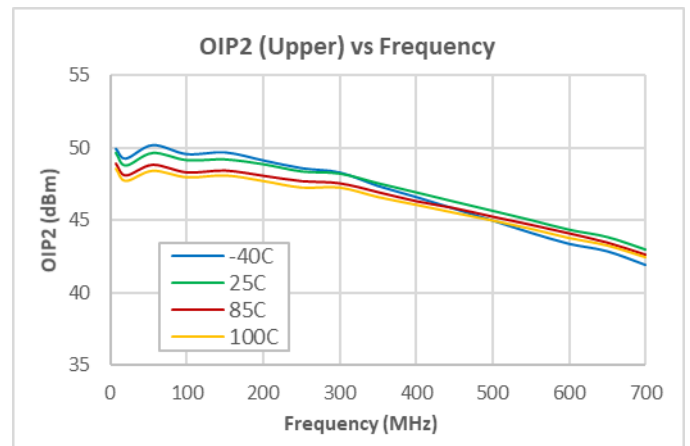
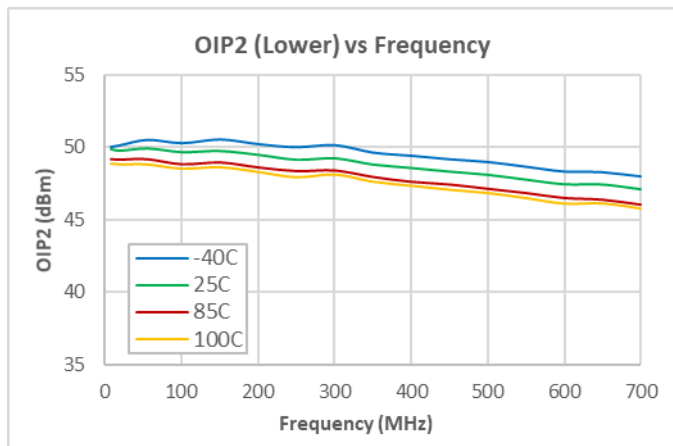
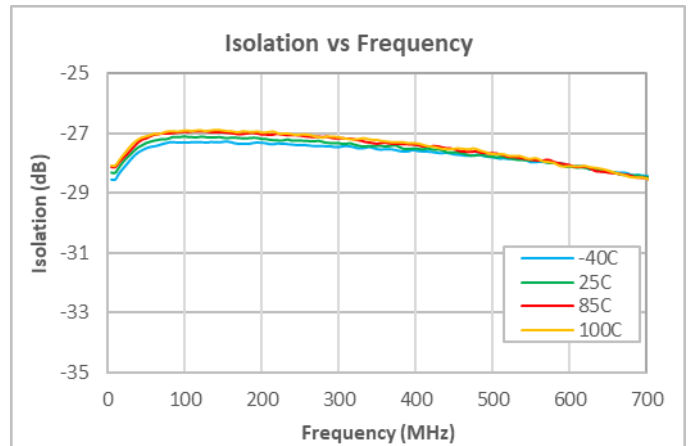
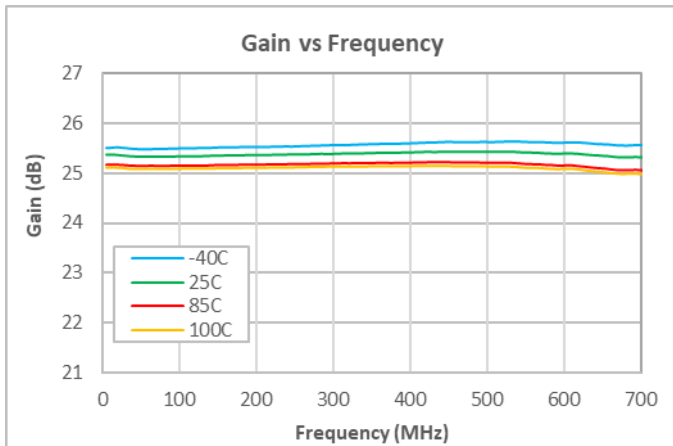
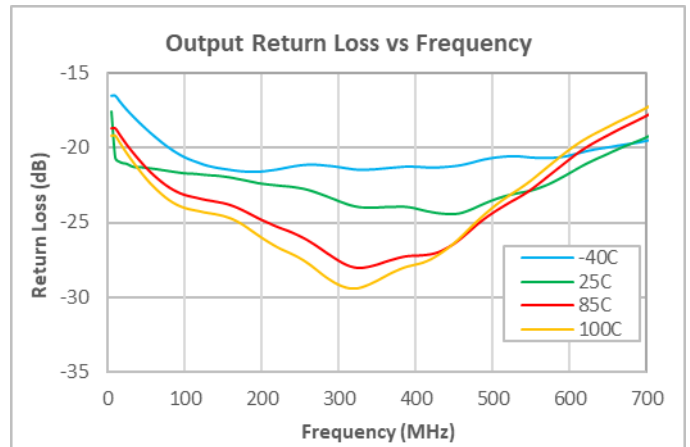
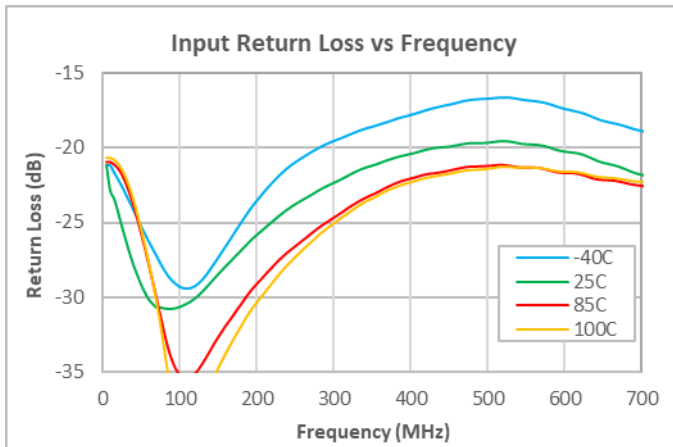
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP3; +9 dBm/tone output, 6 MHz spacing

Performance Data, 5 – 700 MHz (5 V)



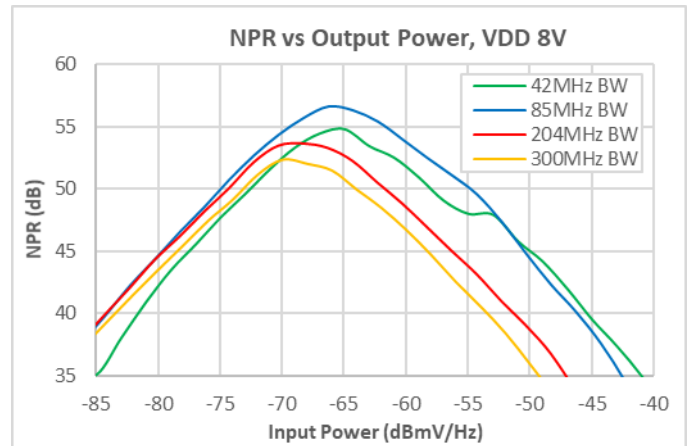
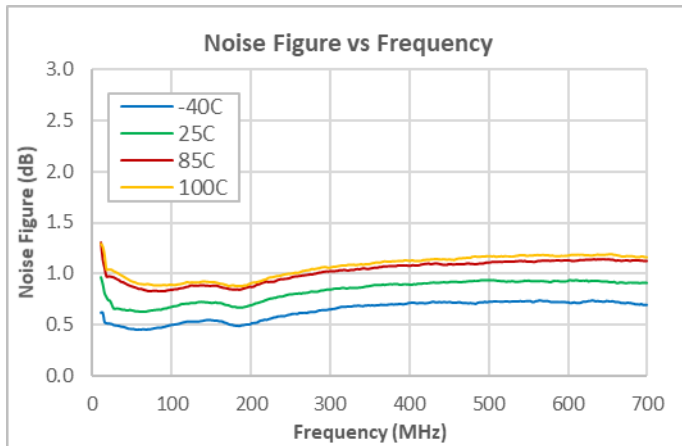
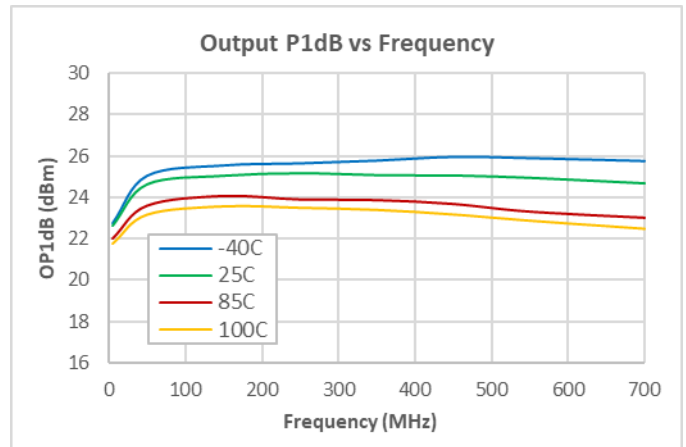
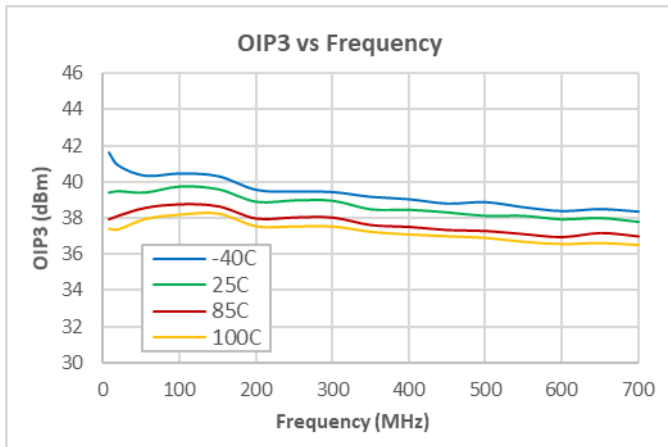
- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) MER/BER; 256 QAM, 0dB Tilt, ITU-T J.83, Annex B, Source Corrected, Maximum Correction 4.3 dB
 - a. 204 MHz; 33Ch. 5 – 204 MHz
 - b. 396 MHz; 65Ch. 5 – 396 MHz
 - c. 684 MHz; 133Ch. 5 – 684 MHz

Performance Data, 5 – 700 MHz (8 V)



- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) OIP2; +9 dBm/tone output, 30 MHz spacing

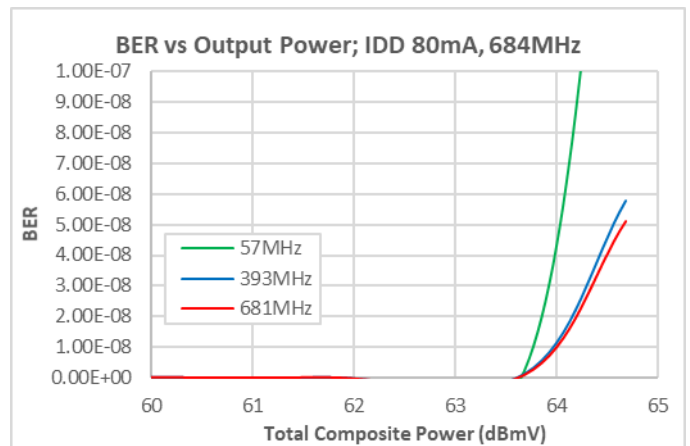
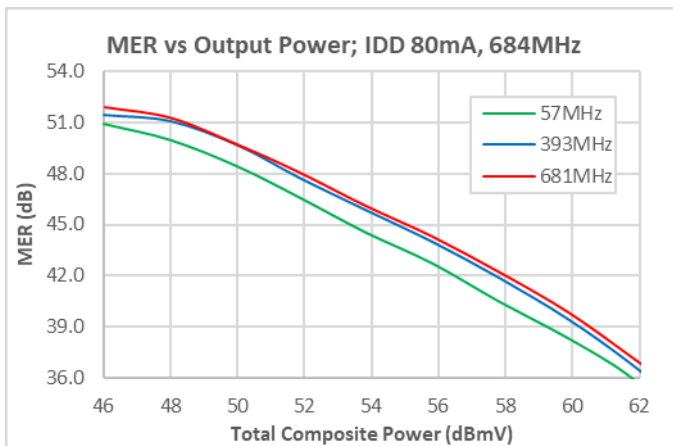
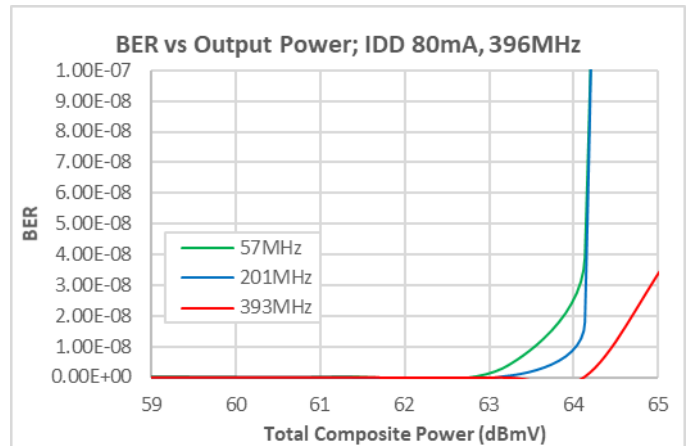
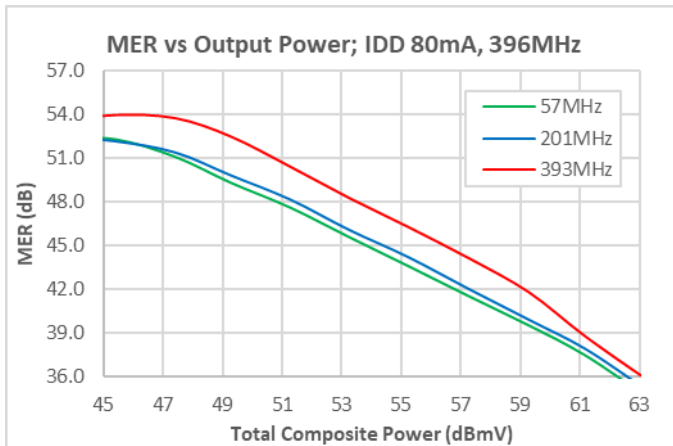
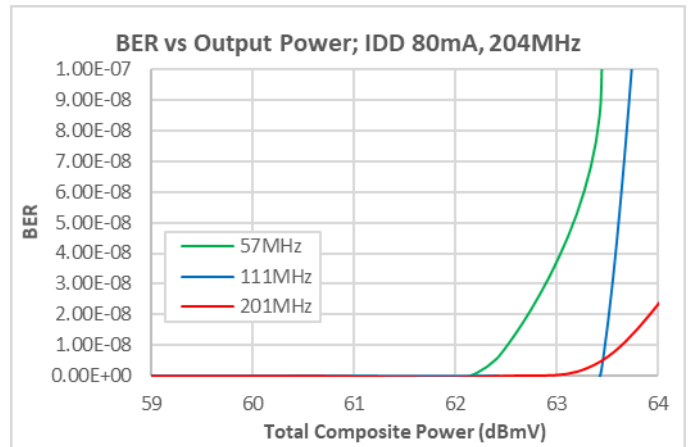
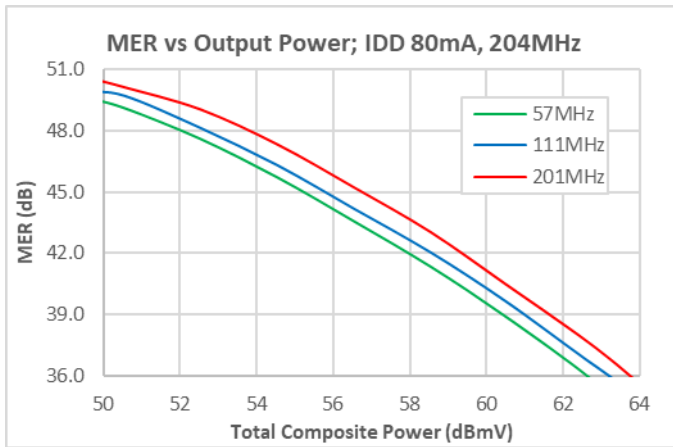
Performance Data, 5 – 700 MHz (8 V)



Notes:

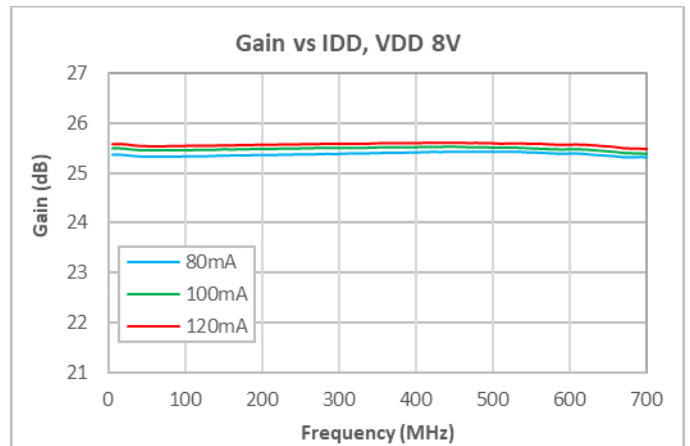
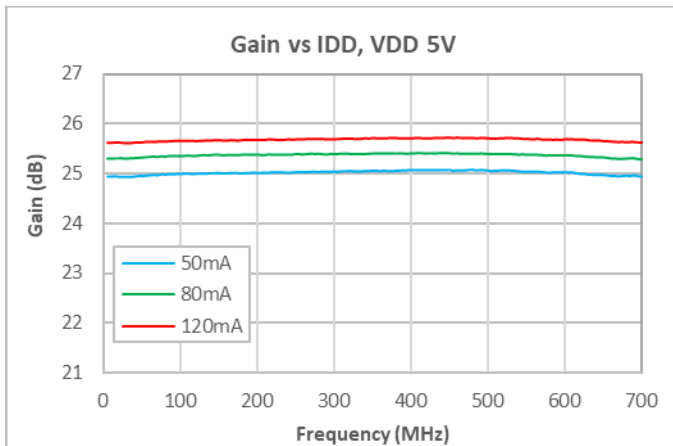
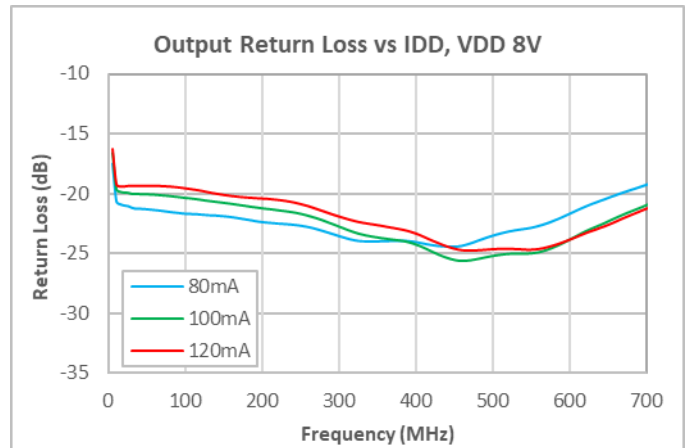
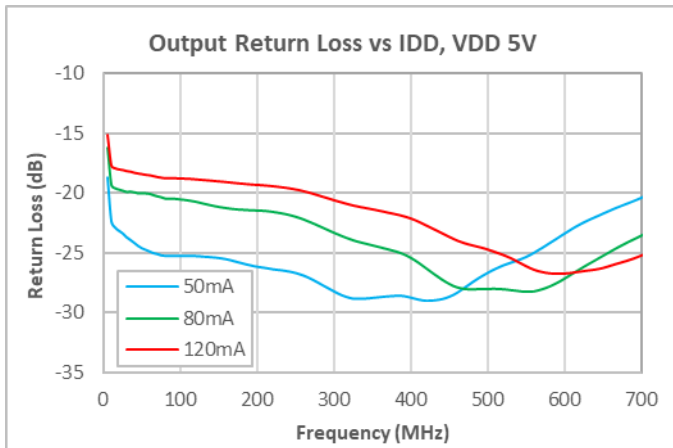
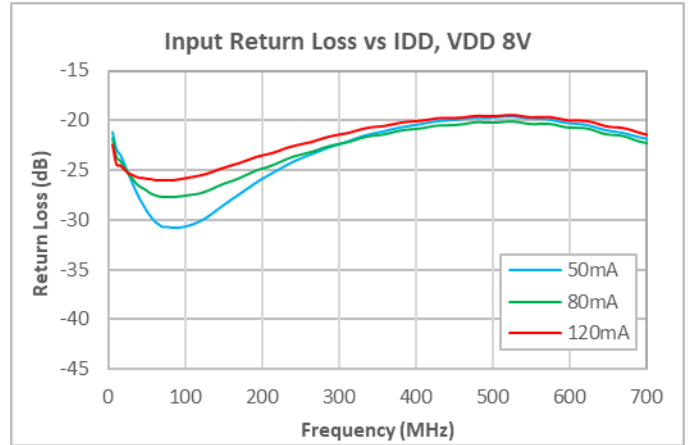
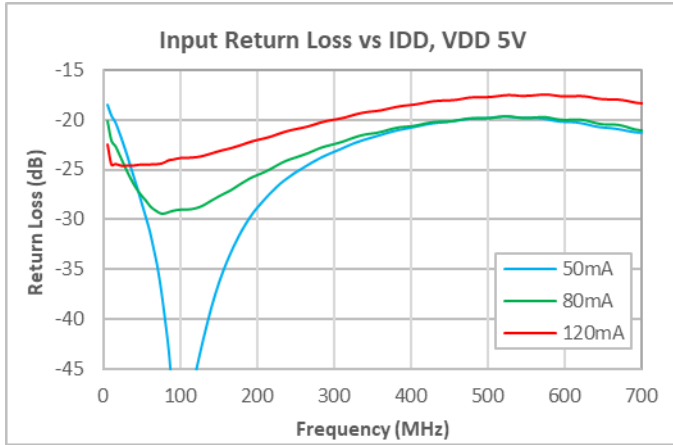
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP3; +9 dBm/tone output, 6 MHz spacing

Performance Data, 5 – 700 MHz (8 V)



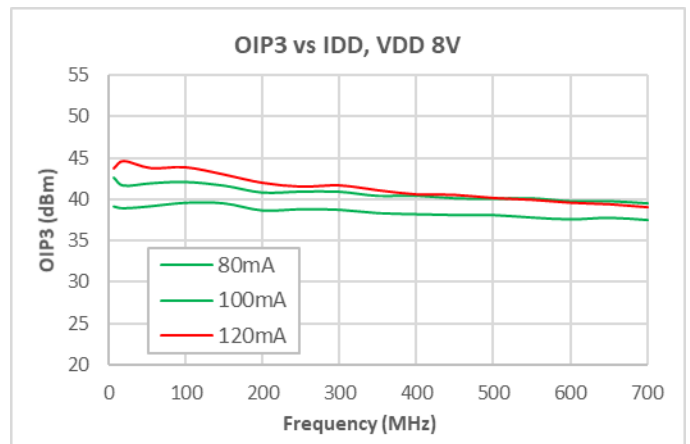
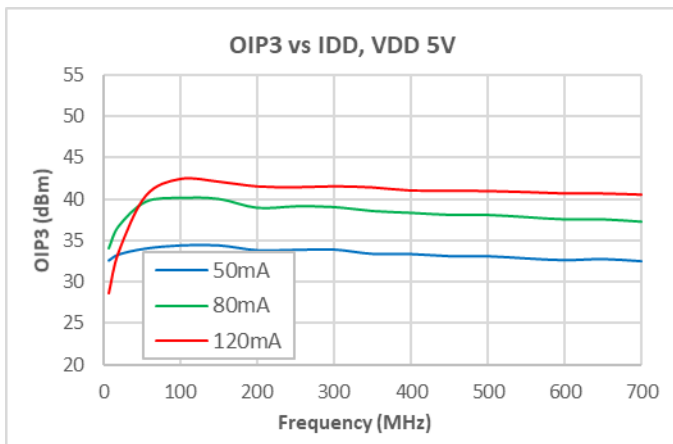
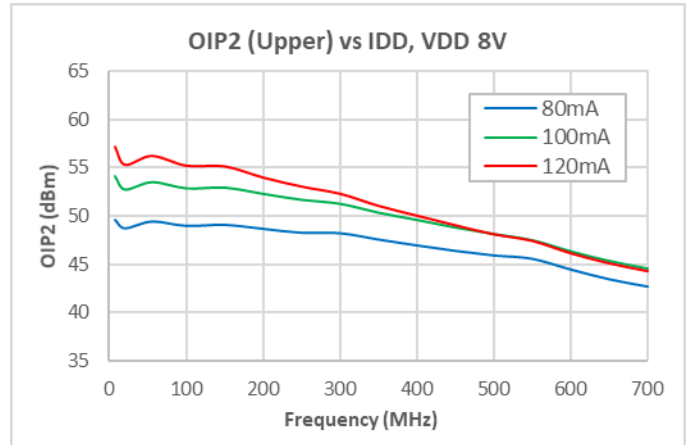
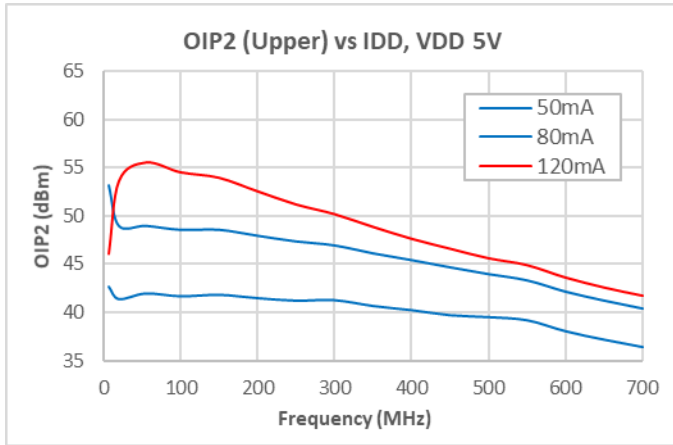
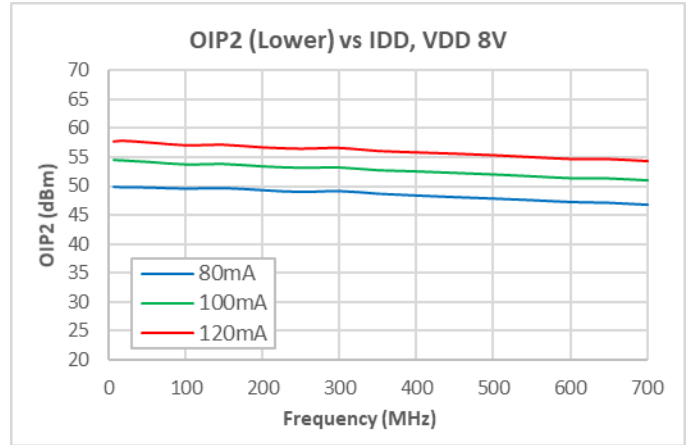
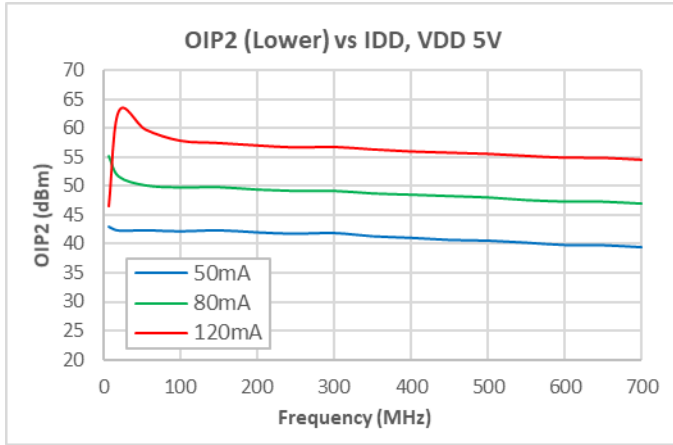
- Notes:
- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
 - (2) MER/BER; 256 QAM, 0dB Tilt, ITU-T J.83, Annex B, Source Corrected, Maximum Correction 4.3 dB.
 - a. 204 MHz; 33Ch. 5 – 204 MHz
 - b. 396 MHz; 65Ch. 5 – 396 MHz
 - c. 684 MHz; 133Ch. 5 – 684 MHz

Performance Data vs Supply Voltage, 5 – 700 MHz



Notes:
 (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).

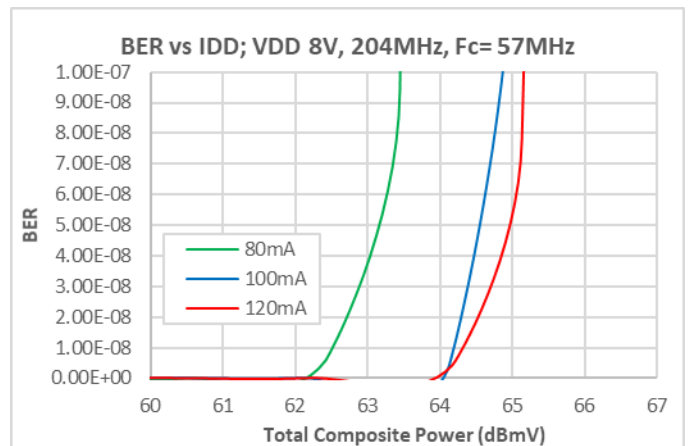
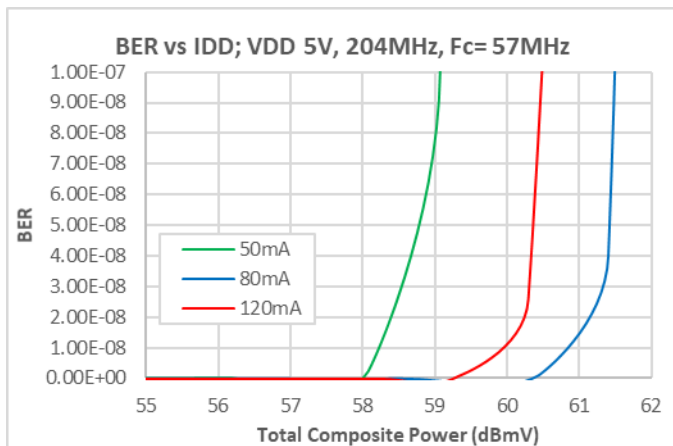
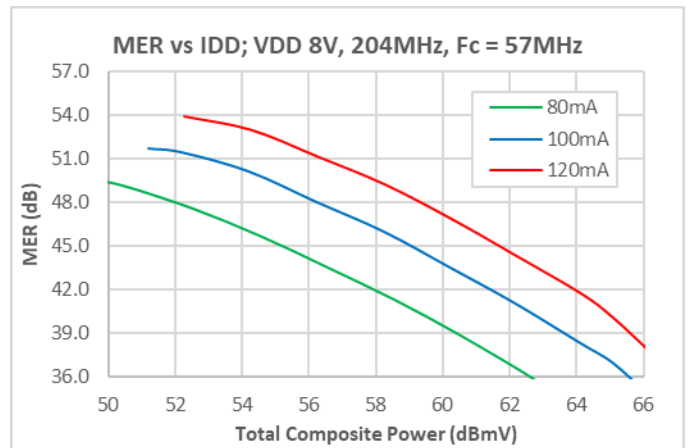
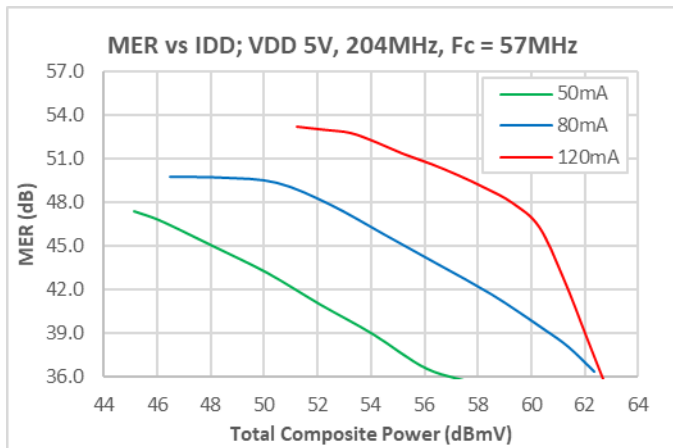
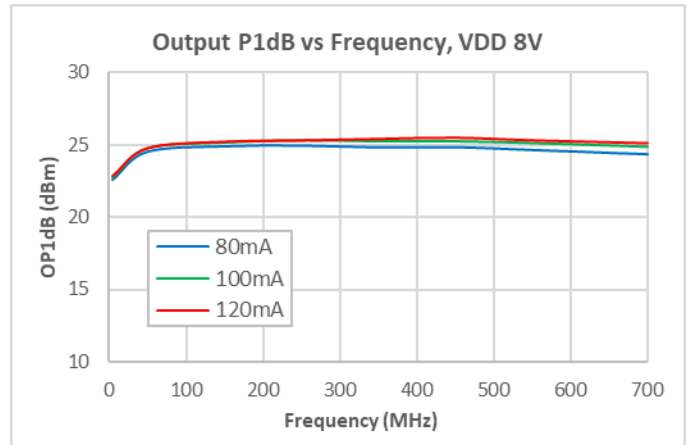
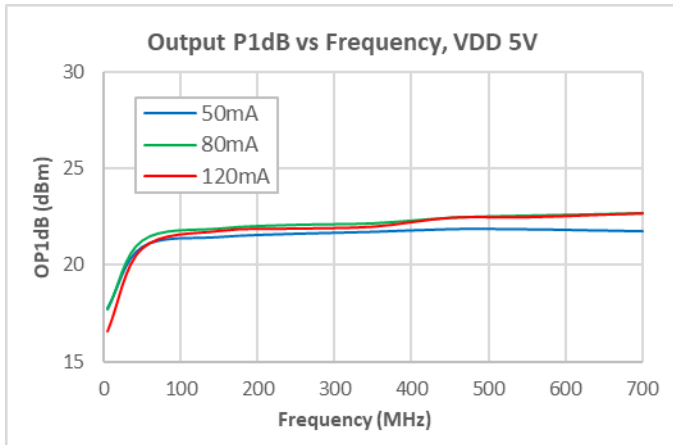
Performance Data vs Supply Voltage, 5 – 700 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) OIP2; 9 dBm/tone, 30 MHz spacing.
- (3) OIP3; 9 dBm/tone, 6 MHz spacing.

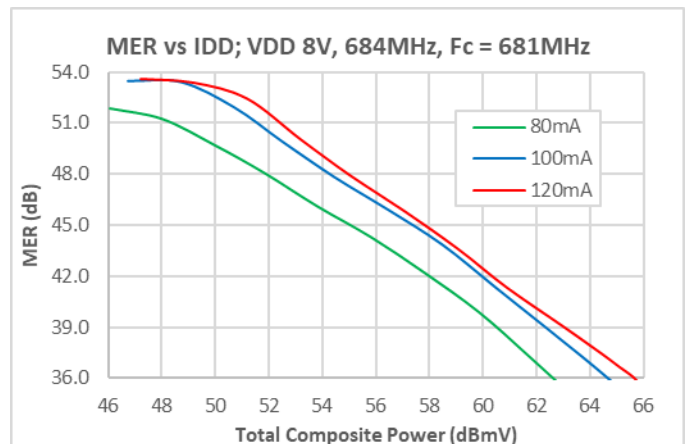
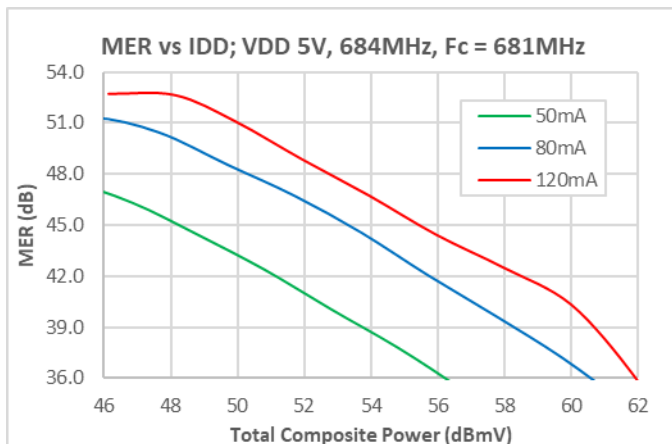
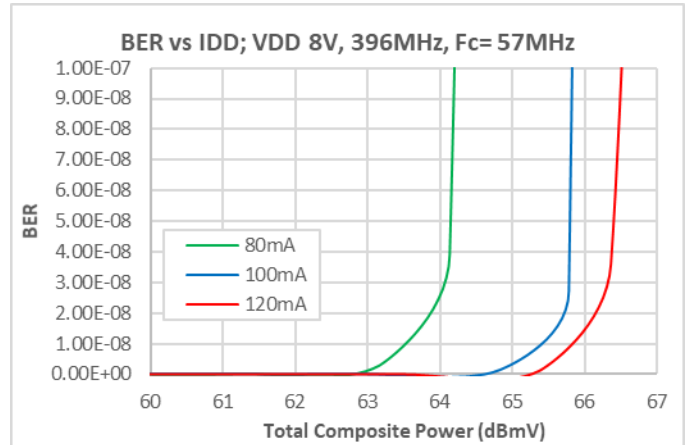
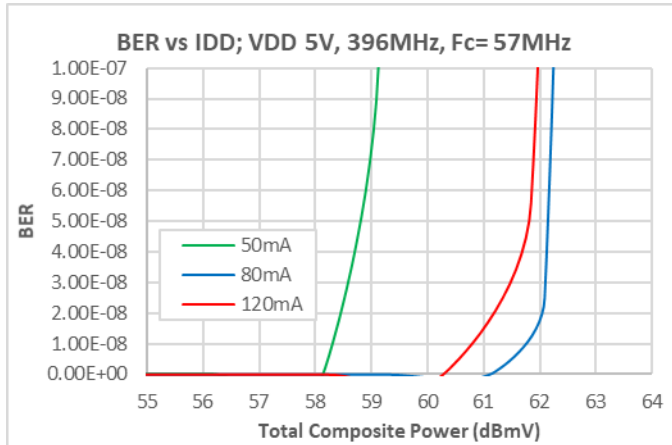
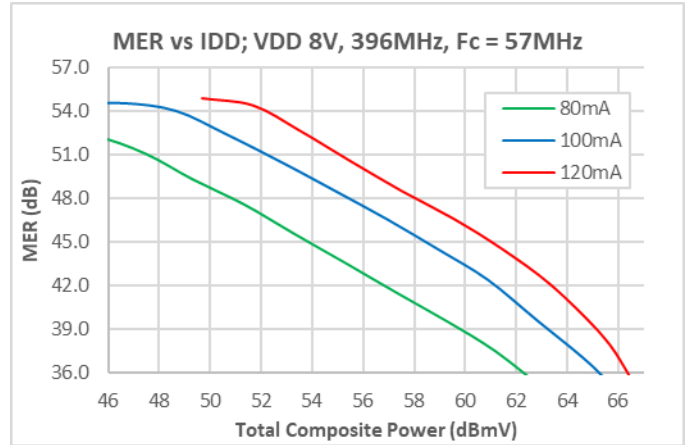
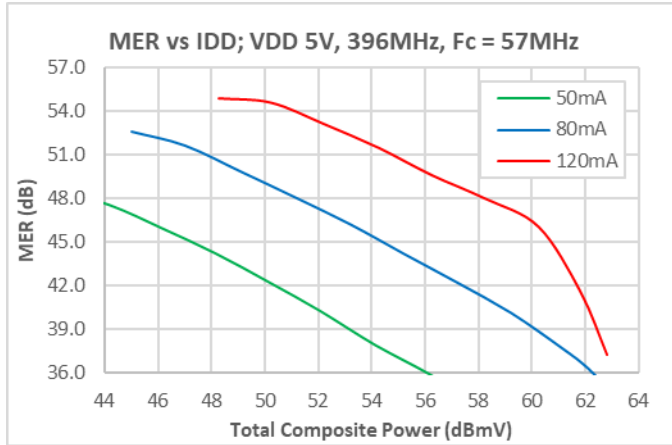
Performance Data vs Supply Voltage, 5 – 700 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) MER/BER; 256 QAM, 0dB Tilt, ITU-T J.83, Annex B, Source Corrected, Maximum Correction 4.3 dB.
 - a. 204 MHz; 33Ch. 5 – 204 MHz
 - b. 396 MHz; 65Ch. 5 – 396 MHz
 - c. 684 MHz; 133Ch. 5 – 684 MHz

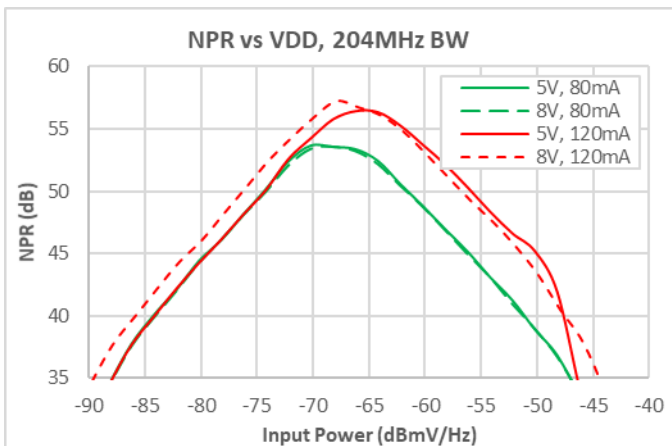
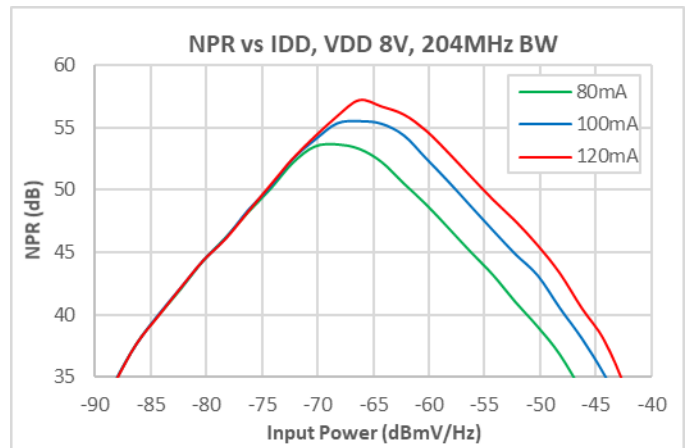
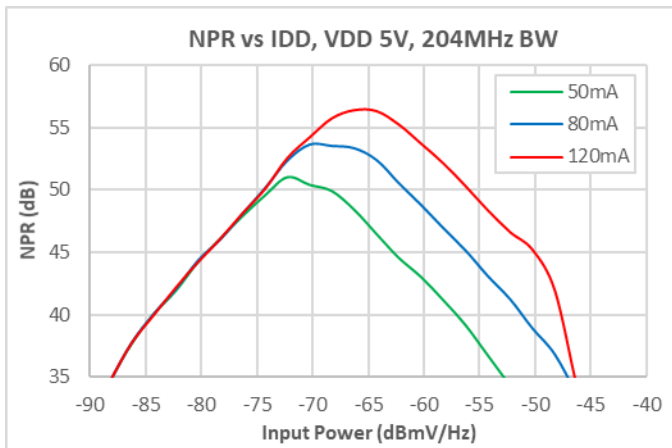
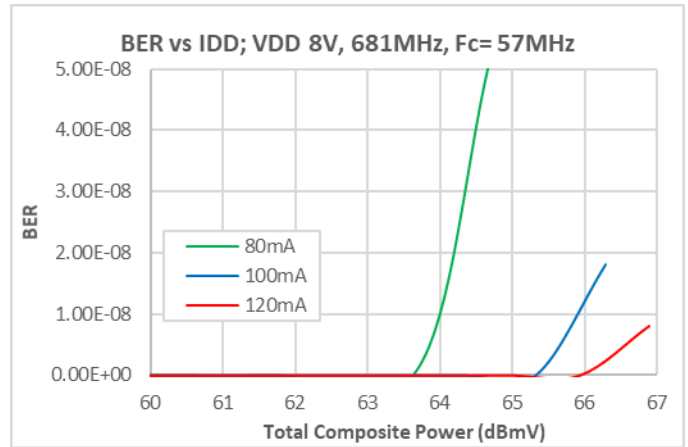
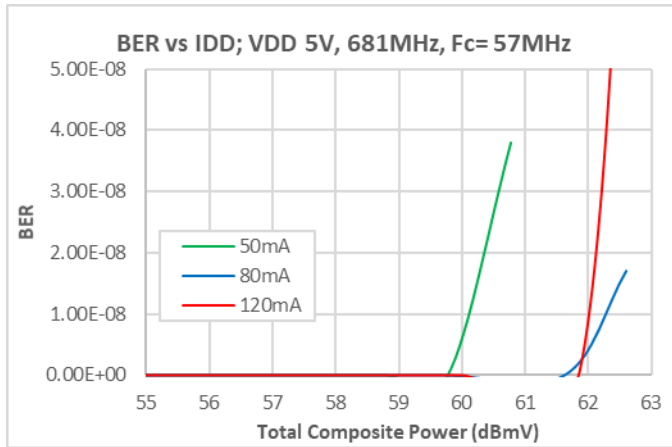
Performance Data vs Supply Voltage, 5 – 700 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) MER/BER; 256 QAM, 0dB Tilt, ITU-T J.83, Annex B, Source Corrected, Maximum Correction 4.3 dB.
 - a. 204 MHz; 33Ch. 5 – 204 MHz
 - b. 396 MHz; 65Ch. 5 – 396 MHz
 - c. 684 MHz; 133Ch. 5 – 684 MHz

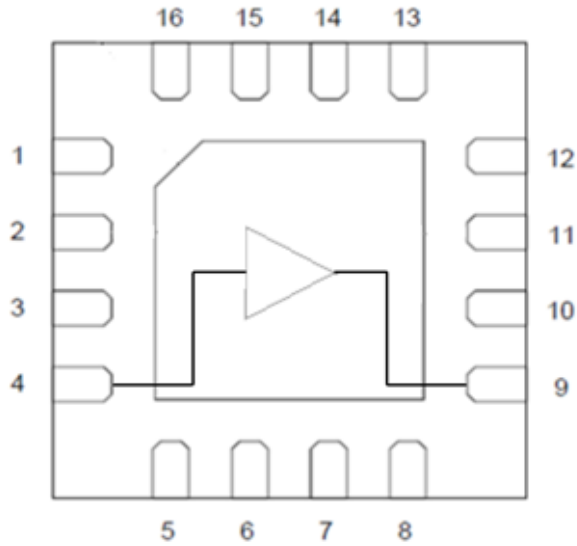
Performance Data vs Supply Voltage, 5 – 700 MHz



Notes:

- (1) Temperature 25 °C, 75 ohm test system, nominal current (unless otherwise noted).
- (2) MER/BER; 256 QAM, 0dB Tilt, ITU-T J.83, Annex B, Source Corrected, Maximum Correction 4.3 dB.
 - a. 204 MHz; 33Ch. 5 – 204 MHz
 - b. 396 MHz; 65Ch. 5 – 396 MHz
 - c. 684 MHz; 133Ch. 5 – 684 MHz

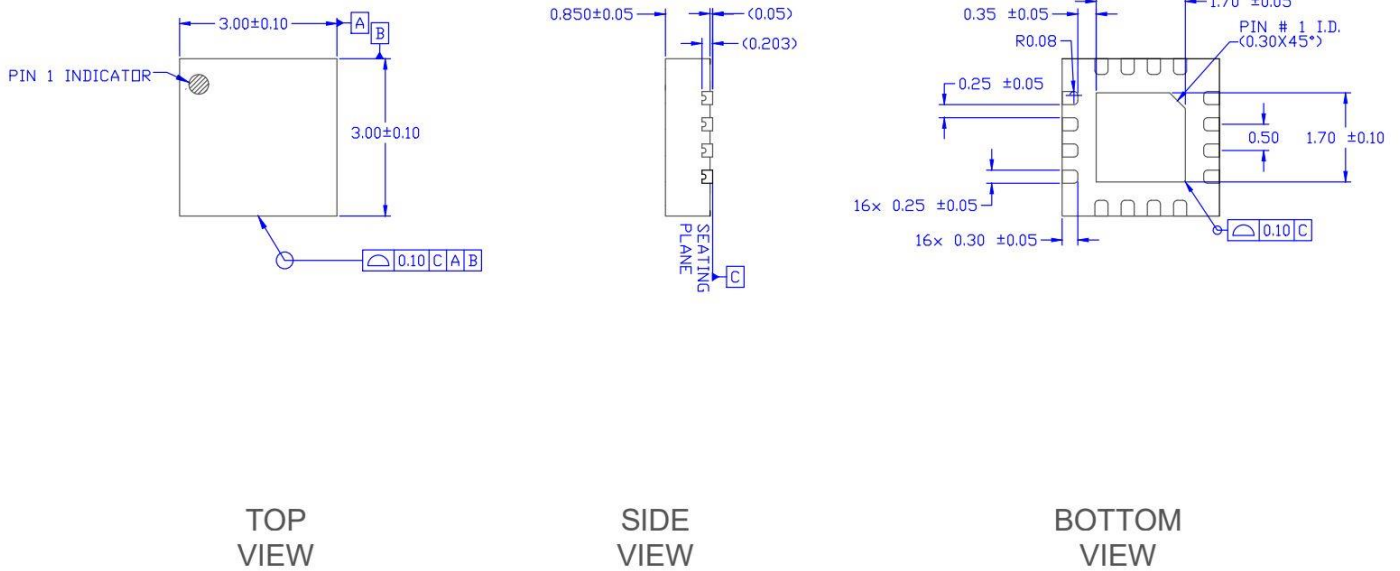
Pin Configuration and Description



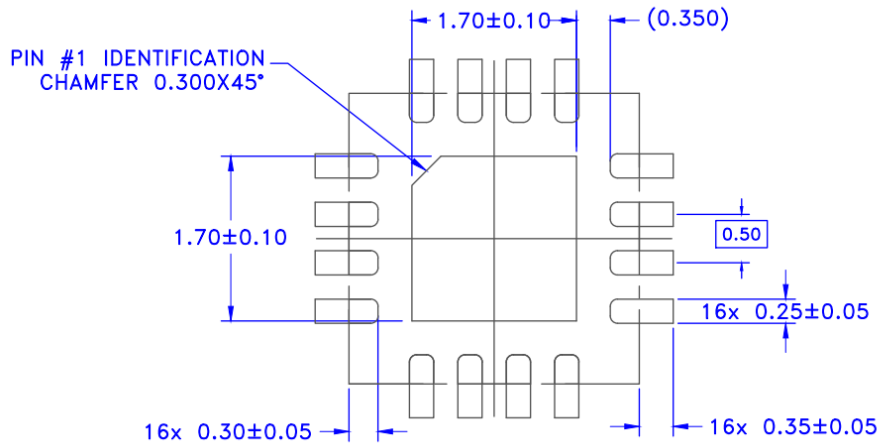
Top View

| Pin Number | Label | Description |
|-------------------|--------------|--|
| 4 | RF IN | RF Input, DC blocking capacitor required. |
| 9 | RF OUT / VDD | RF Output – VDD bias choke required. |
| 1 - 3, 5-8, 10-16 | GND | Internally Not Connected. |
| Backside Paddle | GND | Ground. Use recommended via pattern to minimize inductance and thermal resistance. See PCB Mounting Pattern for suggested footprint. |

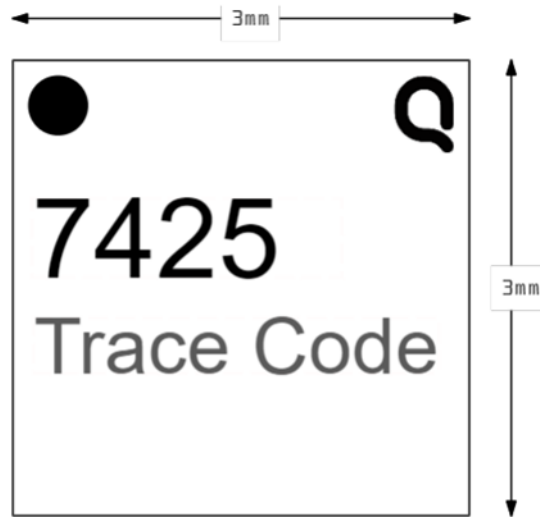
Package Outline



Recommended Mounting Pattern



Package Marking



- Pin 1 Indicator
- Qorvo Logo - Use Q5D
- Trace Code to be assigned by SubCon

Handling Precautions

| Parameter | Rating | Standard |
|----------------------------------|----------------------------|------------------------|
| ESD – Human Body Model (HBM) | Class 1B (500V to < 1000V) | ANSI/ESDA/JEDEC JS-001 |
| ESD – Charged Device Model (CDM) | Class C3 (≥1000V) | ANSI/ESDA/JEDEC JS-002 |
| MSL – Moisture Sensitivity Level | Level 2 | IPC/JEDEC J-STD-020 |



Caution!
ESD-Sensitive
Device

Solderability

Compatible with both lead-free (260 °C max. reflow temp.) and tin/lead (245 °C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: NiPdAu

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Tel: 1-844-890-8163

Web: www.qorvo.com

Email: customer.support@qorvo.com

Important Notice

The information contained in this Data Sheet and any associated documents (“Data Sheet Information”) is believed to be reliable; however, Qorvo makes no warranties regarding the Data Sheet Information and assumes no responsibility or liability whatsoever for the use of said information. All Data Sheet Information is subject to change without notice. Customers should obtain and verify the latest relevant Data Sheet Information before placing orders for Qorvo® products. Data Sheet Information or the use thereof does not grant, explicitly, implicitly or otherwise any rights or licenses to any third party with respect to patents or any other intellectual property whether with regard to such Data Sheet Information itself or anything described by such information.

DATA SHEET INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE. Without limiting the generality of the foregoing, Qorvo® products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death. Applications described in the Data Sheet Information are for illustrative purposes only. Customers are responsible for validating that a particular product described in the Data Sheet Information is suitable for use in a particular application.

© 2023 Qorvo US, Inc. All rights reserved. This document is subject to copyright laws in various jurisdictions worldwide and may not be reproduced or distributed, in whole or in part, without the express written consent of Qorvo US, Inc. | QORVO® is a registered trademark of Qorvo US, Inc.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View QPL7425SR on WIN SOURCE](#)

 [Qorvo US Inc. Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management